

**COURSE STRUCTURE
AND
DETAILED SYLLABUS**

Electronics & Communication Engineering

**M.TECH
VLSI SYSTEM DESIGN**

For

M.TECH. TWO YEAR PG COURSE

(Applicable for the batches admitted from 2025-2026)



VAAGDEVI ENGINEERING COLLEGE

(Autonomous)

Bollikunta, Warangal, Telangana-506 005

VAAGDEVI ENGINEERING COLLEGE
(AUTONOMOUS)
M. TECH IN VLSI SYSTEM DESIGN
COURSE STRUCTURE & SYLLABUS (R25 Regulations)
Applicable from AY 2025-26 Batch

I M.Tech. I Semester

S.No	Course Code	Title of the Course	L	T	P	Credits
1	M25VL101	CMOS Digital IC Design	3	0	0	3
2	M25VL102	CMOS Analog IC Design	3	0	0	3
3	Professional Elective-I		3	0	0	3
	M25VL103	1. Device Modelling				
	M25VL104	2. Embedded Real Time Operating Systems				
	M25VL105	3. Nanomaterials and Nanotechnology				
4	Professional Elective-II		3	0	0	3
	M25CS116	1. Machine Learning and Deep Learning				
	M25VL106	2. VLSI Architectures for Digital Signal Processing				
	M25CS117	3. Scripting Languages for Design Automation				
5	M25VL107	CMOS Digital IC Design Laboratory	0	0	4	2
6	M25VL108	CMOS Analog IC Design Laboratory	0	0	4	2
7	M25MB109	Research Methodology & IPR	2	0	0	2
8		Audit Course-I	2	0	0	0
Total Credits			16	0	8	18

I M.Tech. II Semester

S.No	Course Code	Title of the Course	L	T	P	Credits
1	M25VL201	Mixed Signal IC Design	3	0	0	3
2	M25VL202	FPGA Based System Design	3	0	0	3
3	Professional Elective-III		3	0	0	3
	M25VL203	1. VLSI Test and Testability				
	M25VL204	2. Physical Design Automation with AI				
	M25VL205	3. Functional Verification using System Verilog and UVM				
4	Professional Elective-IV		3	0	0	3
	M25VL206	1. Low Power VLSI Design				
	M25VL207	2. Microchip Fabrication Techniques				
	M25VL208	3. Power Management IC Design				
5	M25VL209	Mixed Signal IC Design Laboratory	0	0	4	2
6	M25VL210	FPGA Based System Design Laboratory	0	0	4	2
7	M25VL211	Mini Project with Seminar	0	0	4	2
8		Audit Course-II	2	0	0	0
Total Credits			14	0	12	18

II M.Tech. I Semester

S.No	Course Code	Title of the Course	L	T	P	Credits
Professional Elective-V						
1	M25VL301	1. CMOS RF IC Design	3	0	0	3
	M25VL302	2. Hardware Security in VLSI Design				
	M25VL303	3. Advanced Memory Design and Architectures				
2		Open Elective	3	0	0	3
3	M25VL304	Dissertation Work Review-II	0	0	18	6
Total Credits			6	0	18	12

II M.Tech. II Semester

S.No	Course Code	Title of the Course	L	T	P	Credits
1	M25VL401	Dissertation Work Review-III	0	0	18	06
2	M25VL402	Dissertation Viva-Voce	0	0	42	14
Total Credits			0	0	60	20

Open Electives

S.No	Course Code	Title of the Course
1	M25MB309	Business Analytics
2	M25VL305	Industrial Safety
3	M25VL306	Operations Research
4	M25MB310	Cost Management of Engineering Projects
5	M25VL307	Composite Materials

Audit Courses

S.No	Course Code	Title of the Course
1	M25AC101	English for Research Paper Writing
2	M25AC102	Disaster Management
3	M25AC103	Sanskrit for Technical Knowledge
4	M25AC104	Value Education
5	M25AC105	Constitution of India
6	M25AC106	Pedagogy Studies
7	M25AC107	Stress Management by Yoga
8	M25AC108	Personality Development Through Life Enlightenment Skills

CMOS Digital IC Design

M.Tech. I Year I Sem.

L T P C

Course Code: M25VL101

3 0 0 3

Course Overview:

This course introduces students to the foundational and advanced concepts in CMOS (Complementary Metal-Oxide-Semiconductor) digital integrated circuit design. Students will explore the principles, performance metrics, and design strategies for static and dynamic CMOS inverters, combinational and sequential logic gates, and complex digital systems. Emphasis is placed on understanding trade-offs in performance, power, area, and reliability in the context of technology scaling. The course also addresses interconnect modelling and modern layout methodologies, equipping students with practical and theoretical tools for custom and semi-custom digital IC design.

Course Outcomes (COs)

By the end of the course, students will be able to:

1. Analyse static and dynamic behaviour of CMOS inverters using key performance metrics.
2. Design combinational logic circuits using static and dynamic CMOS styles.
3. Implement various sequential logic elements and pipelining techniques.
4. Apply custom and semi-custom design methodologies for digital ICs.
5. Evaluate interconnect effects and apply techniques to reduce parasitic impact.

Syllabus

Unit I:

The CMOS Inverter: Introduction, the static CMOS inverter, Evaluating the robustness of the CMOS inverter – static behavior, Performance of CMOS inverter – dynamic behavior, Power, energy and energy-delay, Technology scaling and its impact on the inverter metrics.

Unit II:

Designing Combinational Logic Gates in CMOS: Introduction, Static CMOS design – complementary CMOS, ratioed logic, pass-transistor logic, Dynamic CMOS design – basic principles, speed and power dissipation of dynamic logic, Issues in dynamic design, cascading dynamic gates, Choosing a logic style, Designing logic for reduced supply voltage.

Unit III:

Designing Sequential Logic Circuits: Introduction – timing metrics for sequential circuits, Classification of memory elements, Static latches and registers – bistability principle, multiplexer-based latches, master-slave edge-triggered register, Low-voltage static latches, static SR flip-flops, Dynamic latches and registers – transmission gate edge-triggered registers, C2MOS, TSPCR, Pipelining – latch vs. register-based pipelines, NORA-CMOS

Unit IV:

Implementation Strategies for Digital ICs: Introduction, From custom to semi-custom and structured array design approaches, Custom circuit design, Cell-based design methodology, Array-based implementation approaches.

Unit V:

Coping with Interconnect: Introduction, Capacitive parasitics, Resistive parasitics, Inductive parasitics, Advanced interconnect techniques.

Text Book

1. Rabaey, Jan M., Anantha Chandrakasan, and Borivoje Nikolic. Digital Integrated Circuits: A Design Perspective. 2nd ed., Pearson Education, 2003.

Reference Books

1. Kang, Sung-Mo (Steve), and Yusuf Leblebici. CMOS Digital Integrated Circuits: Analysis and Design. 3rd ed., McGraw-Hill, 2003.
2. Uyemura, John P. Introduction to VLSI Circuits and Systems. Wiley, 2002.
3. Weste, Neil H.E., and David Harris. CMOS VLSI Design: A Circuits and Systems Perspective. 4th ed., Pearson Education, 2011.

CMOS Analog IC Design

M.Tech. I Year I Sem.

Course Code: M25VL102

L T P C

3 0 0 3

Course Overview:

This course provides a comprehensive foundation in CMOS Analog Integrated Circuit Design, focusing on the analysis and design of key analog building blocks used in modern VLSI systems. It covers essential topics such as MOS device physics, single-stage and differential amplifiers, current mirrors, and operational amplifiers. Emphasis is placed on understanding the small-signal behavior, frequency response, and performance trade-offs in analog circuits. Students will gain skills in applying transistor-level models, analyzing analog circuit topologies, and designing biasing schemes, enabling them to develop robust analog IC solutions for real-world applications in consumer electronics, communications, and sensor interfaces.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Apply MOS device characteristics and second-order effects to analog circuit analysis.
2. Design single-stage MOS amplifier configurations for specific gain and impedance requirements.
3. Analyze the performance of differential amplifiers under common-mode and differential-mode operation.
4. Apply current mirror topologies to design biasing circuits in CMOS analog design.
5. Compare operational amplifier topologies considering gain, bandwidth, and power trade-offs.

Syllabus

Unit I:

MOS Device Physics and Models: Introduction to analog design, MOS device physics – General Considerations, MOS I/V Characteristics, Second-Order Effects, MOS Device Models.

Unit II:

Single Stage Amplifiers: Basic Concepts, Common-Source Stage with resistive-load and diode connected load, Source Follower, Common-Gate Stage.

Unit III:

Differential Amplifiers: Single-Ended and Differential Operation, Basic Differential Pair, Common-Mode Response, Differential Mode with MOS Loads, Gilbert Cell.

Unit-IV

Passive and Active Current Mirrors: Basic Current Mirrors, Cascode Current Mirrors, Active Current Mirrors

Unit-V:

Operational Amplifiers: General Considerations, One-Stage Op Amps, Two-Stage Op Amps, Gain Boosting, Comparison.

Text Book

1. Razavi, Behzad. Design of Analog CMOS Integrated Circuits. McGraw-Hill Education, 2001.

Reference Books

1. Allen, Philip E., and Douglas R. Holberg. CMOS Analog Circuit Design. 3rd ed., Oxford University Press, 2011.
2. Johns, David A., and Ken Martin. Analog Integrated Circuit Design. Wiley India, 2015.
3. Sansen, Willy M.C. Analog Design Essentials. Springer, 2006.

Device Modeling

M.Tech. I Year I Sem.

L T P C

Course Code: M25VL103

3 0 0 3

Course Overview:

This course focuses on the theoretical foundations and practical techniques for modeling MOSFET devices in the context of VLSI circuit design. It provides an in-depth understanding of semiconductor device physics, MOS capacitor behavior, MOSFET current-voltage characteristics, and advanced modeling concepts including capacitance, reliability, and parameter extraction. The course also covers how these models are integrated into simulation tools such as SPICE, enabling accurate performance prediction in modern IC design.

Course Outcomes (COs):

By the end of this course, students will be able to:

1. Explain the physical structure and electrical behavior of MOSFET devices.
2. Analyze and model MOS capacitors and threshold voltage characteristics.
3. Develop current-voltage and capacitance models for MOSFETs.
4. Evaluate device reliability issues and implement SPICE-based models.
5. Apply parameter extraction techniques and statistical modeling in circuit simulation.

Syllabus

Unit I:

Fundamentals of MOSFET Structure and Device Physics: Review of semiconductor physics and p–n junction, MOS transistor structure and operation, Scaling effects and parasitics, Modern VLSI device structures

Unit-II:

MOS Capacitor and Threshold Voltage Modeling: MOS capacitor - physics and C–V characteristics, Threshold voltage modeling: uniform and nonuniform doping, Short-channel effects: DIBL, narrow-width effect, Temperature dependence of threshold voltage

Unit-III:

DC and Dynamic Modeling of MOSFETs: Charge-sheet and Pao–Sah current models,

Subthreshold conduction and mobility degradation, Temperature effects on current characteristics, Capacitance models: Meyer model, charge-based model, Small-signal modeling

Unit-IV:

Reliability Modeling and SPICE Device Models: Hot-carrier degradation and reliability concerns, Gate and substrate currents, SPICE MOSFET models: LEVEL 1, 2, 3, Parameter definitions and usage in simulation

Unit-V:

Parameter Extraction and Statistical Modeling: Measurement techniques: C–V, threshold voltage, mobility, Parameter extraction using optimization techniques, Statistical modeling for process variation, Worst-case modeling in VLSI design

Textbook

1. Arora, Narain. MOSFET Modeling for VLSI Simulation: Theory and Practice. Springer Science & Business Media, 2007.

Reference Books

1. Tsividis, Yannis, and Colin McAndrew. Operation and Modeling of the MOS Transistor. 3rd ed., Oxford University Press, 2011.
2. Sze, S. M., and Kwok K. Ng. Physics of Semiconductor Devices. 3rd ed., Wiley, 2006.
3. Trivedi, Subarna S., and Saurabh Kumar Gupta. Semiconductor Device Modeling and Technology. PHI Learning, 2012.
4. Muller, Richard S., and Theodore I. Kamins. Device Electronics for Integrated Circuits. 3rd ed., Wiley, 2002.

Embedded Real Time Operating Systems

M.Tech. I Year I Sem.

L T P C

Course Code: M25VL104

3 0 0 3

Course Overview:

This course provides a comprehensive introduction to Real-Time Operating Systems (RTOS) and their applications in embedded systems. Students will explore the fundamental concepts of real-time embedded systems, understand task management, synchronization mechanisms like semaphores and message queues, and delve into exception handling and timer services. The course also covers memory management strategies and practical techniques for modularizing applications to meet real time constraints. Additionally, it addresses common design challenges such as deadlocks and priority inversion, preparing students to design, analyse, and implement robust real-time embedded applications.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Analyse key concepts and roles of real-time operating systems in embedded system design.
2. Evaluate task scheduling and synchronization methods in real-time systems.
3. Design interrupt and timer handling mechanisms for embedded real-time environments.
4. Apply real-time memory management techniques in embedded applications.
5. Create modular real-time applications to resolve deadlocks and priority inversion.

Syllabus

Unit-I:

Introduction to RTOS: Real life examples of embedded systems, real-time embedded systems, the future of embedded systems, a brief history of operating systems, defining an RTOS, the scheduler, objects, services, key characteristics of an RTOS.

Unit-II:

Tasks: Introduction, defining a task, task states and scheduling, typical task operations, typical task structure, synchronization, communication, and concurrency.

Semaphores: Introduction, defining semaphores, typical semaphore operations, typical semaphore use.

Message Queues: Introduction, defining message queues, message queue states, message queue content, message queue storage, typical message queue operations, and typical message queue use.

Unit-III:

Exceptions and Interrupts: Introduction, what are exceptions and interrupts, a closer look at exceptions and interrupts, processing general exceptions, the nature of spurious interrupts. Timer and Timer Services: Introduction, real-time clocks and system clocks, programmable interval timers, timer interrupt service routines, a model for implementing the soft-timer handling facility, timing wheels, soft timers and timer related operations.

Unit-IV:

Memory Management: Introduction, dynamic memory allocation in embedded systems, fixed-size memory management in embedded systems, blocking vs. non-blocking memory functions, hardware memory management units.

Unit-V:

Modularizing Applications: Introduction, an outside-in approach to decomposing applications, guidelines and recommendations for identifying concurrency, schedulability analysis – rate monotonic analysis.

Common Design Problems: Introduction, resource classification, deadlocks, priority inversion.

Text Book

1. Qing Li, and Caroline Yao. Real-Time Concepts for Embedded Systems. CMP Books, 2003.

Reference Books

1. Prasad, K. V. K. K. Embedded Real-Time Systems: Concepts, Design & Programming. Dream Tech Press, 2005.
2. Simon, David E. An Embedded Software Primer. 1st ed., 5th impression, Addison-Wesley Professional, 2007.
3. Singh, Rajib Mall. Real-Time Systems: Theory and Practice. Pearson Education India, 2006.

Nanomaterials and Nanotechnology

M.Tech. I Year I Sem.

Course Code: M25VL105

L T P C

3 0 0 3

Course Overview:

This course explores the fundamentals and advanced concepts of nanomaterials and nanotechnologies. It covers the unique physical and chemical properties of nanostructures across different dimensions (0D, 1D, 2D, and 3D), their synthesis methods, and applications. Students will learn about the size-dependent effects on material properties, nanolithography techniques, and the integration of nanomaterials in devices like MEMS and nanoelectronics. Special emphasis is placed on carbon nanotubes (CNTs), ferroelectric materials, and emerging applications in biology, environment, and electronics.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Describe the fundamental properties and classification of nanomaterials across different dimensions.
2. Explain the various synthesis methods for nanostructures and their suitability for scaling applications.
3. Illustrate the working principles and fabrication processes of MEMS and nanolithography techniques.
4. Analyze the growth mechanisms, properties, and applications of carbon nanotubes (CNTs).
5. Evaluate the emerging applications of advanced nanomaterials in electronics, biology, and environmental fields.

Syllabus

Unit-I:

Introduction to Nanomaterials and Nanotechnologies: Features of nanostructures, Applications of nanomaterials and technologies, Nano-dimensional materials 0D, 1D, 2D structures, Size effects, Fraction of surface atoms, Specific surface energy, Surface stress, Effect on the lattice parameter, Phonon density of states, General methods for synthesis of nanostructures, Precipitative methods, Reactive methods, Hydrothermal/solvothermal methods, Suitability of synthesis methods for scaling, Potential uses.

Unit-II:

Fundamentals and Classification of Nanomaterials: Classification of nanomaterials, Zero dimensional nanomaterials, One-dimensional nanomaterials, Two-dimensional nanomaterials, Three-dimensional nanomaterials, Low-dimensional nanomaterials and applications, Synthesis, properties and applications of low-dimensional carbon-related nanomaterials.

Unit-III:

Micro- and Nanolithography Techniques and MEMS: Micro- and nanolithography techniques, Emerging applications, Introduction to MEMS, Advantages and challenges of MEMS, Fabrication technologies, Surface micromachining, Bulk micromachining, Molding, Introduction to nanophotonics.

Unit-IV:

Carbon Nanotubes (CNTs): Introduction to CNTs, Synthesis of CNTs (arc-discharge, laser ablation, catalytic growth), Growth mechanisms of CNTs, Multi-walled nanotubes, Single-walled nanotubes, Optical properties of CNTs, Electrical transport in perfect nanotubes, Applications of CNTs.

Unit-V:

Advanced Nanomaterials and Applications: Ferroelectric materials, Coating, Molecular electronics, Nanoelectronics, Biological and environmental applications, Membrane-based applications, Polymer-based applications.

Text Book

1. I. Gusev and A. A. Rempel. Nanocrystalline Materials. Cambridge International Science Publishing; 1st Indian edition, Viva Books Pvt. Ltd., 2008.
2. B. S. Murty, P. Shankar, Baldev Raj, B. B. Rath, and James Murday. Nanoscience and Nanotechnology. Tata McGraw-Hill Education, 2012.

Reference Books

1. Kenneth J. Klabunde and Ryan M. Richards, editors. Nanoscale Materials in Chemistry. 2nd ed., John Wiley & Sons, 2009.
2. Bharat Bhushan. Springer Handbook of Nanotechnology. 3rd ed., Springer, 2010.
3. Kamal K. Kar. Carbon Nanotubes: Synthesis, Characterization and Applications. 1st ed., Research Publishing Services, 2011.

Machine Learning and Deep Learning

M.Tech. I Year I Sem.

Course Code:M25CS116

L T P C

3 0 0 3

Course Overview

This course introduces the principles and practices of Machine Learning and Deep Learning, focusing on both theoretical understanding and practical implementation. It begins with the fundamentals of machine learning, including learning paradigms, model evaluation, and the challenges that have led to deep learning advances. The course then explores deep neural architectures, including feedforward networks, convolutional and recurrent networks, alongside critical concepts such as regularization and optimization. Finally, students are equipped with practical methodologies for building robust models and exposed to real-world applications across computer vision, speech recognition, and natural language processing.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Analyse machine learning algorithms and evaluate model performance using concepts like overfitting, bias-variance, and likelihood-based estimation.
2. Design deep feedforward neural networks using appropriate architectures, activation functions, and backpropagation techniques.
3. Apply regularization and optimization techniques to improve generalization and training efficiency of deep neural networks.
4. Implement convolutional and recurrent neural network models for processing spatial and sequential data.
5. Evaluate model performance and deployment strategies in real-world applications such as computer vision, NLP, and speech recognition.

Syllabus

Unit-I:

Machine Learning Basics: Learning algorithms, Capacity, overfitting and underfitting, estimators, bias and variance, maximum likelihood estimation, Bayesian statistics, Supervised and unsupervised learning algorithms, building a machine learning algorithm, challenges motivating deep learning.

Unit-II:

Deep Feedforward Networks: Gradient-based learning, hidden units, architecture design, backpropagation and other differentiation algorithms.

Unit-III:

Regularization for Deep Learning: Norm penalties, Dataset augmentation, multi-task learning, early stopping, sparse representations, ensemble methods, dropout. Optimization: Optimization for Training Deep Models, challenges in neural network optimization, basic algorithms, parameter initialization strategies, algorithms with adaptive learning rates.

Unit-IV:

Convolutional Neural Networks: The convolution operation, motivation, pooling, convolution and pooling as an infinitely strong prior, variants of the basic convolution function, structures outputs, data types, efficient convolution algorithms, random or unsupervised features.

Sequence Modeling:

Recurrent and Recursive Nets, Recurrent Neural Networks, Recursive Neural Networks, Long Short-Term Memory, optimization for long-term dependencies.

Unit-V:

Practical Methodology: Performance metrics, selecting hyperparameters, debugging strategies. Applications: Large-scale deep learning, computer vision, speech recognition, natural language processing, other applications.

Text Book

1. Goodfellow, Ian, Yoshua Bengio, and Aaron Courville. Deep Learning. MIT Press, 2016.

Reference Books

1. Géron, Aurélien. Hands-On Machine Learning with Scikit-Learn, Keras, and TensorFlow. 2nd ed., O'Reilly Media, 2019.
2. Bishop, Christopher M. Pattern Recognition and Machine Learning. Springer, 2006.
3. Chollet, François. Deep Learning with Python. 2nd ed., Manning Publications, 2021.

VLSI Architectures for Digital Signal Processing

M.Tech. I Year I Sem.

Course Code: M25VL106

L T P C

3 0 0 3

Course Overview

This course provides a comprehensive study of Very Large-Scale Integration (VLSI) architectures tailored for Digital Signal Processing (DSP) systems. It explores the principles, techniques, and hardware implementations that support high-performance DSP applications in modern CMOS technologies. Topics include algorithmic representations, iteration bounds, pipelining, parallelism, unfolding, folding, and convolution techniques, as well as bit-level and redundant arithmetic architectures. The course also introduces the design and use of programmable DSP processors, with a focus on real-time, low-power, and high-throughput design requirements.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Identify typical DSP algorithms and analyze their computational requirements for efficient VLSI implementation.
2. Compute iteration bounds and apply retiming techniques to optimize DSP data flow graphs for performance.
3. Design pipelined and parallel FIR filters and utilize unfolding and folding methods for architectural transformations.
4. Implement fast convolution methods and develop efficient bit-level and redundant arithmetic units for DSP systems.
5. Evaluate and compare programmable DSP processor architectures for various application domains such as mobile and multimedia systems

Syllabus

Unit I:

Introduction to Digital Signal Processing Systems: Introduction, typical DSP algorithms, DSP application demands and scaled CMOS technologies. Iteration Bound: data-flow graph representations, loop bound, and iteration bound, algorithms for computing iteration bound. Pipelining and Parallel Processing: Introduction, pipelining of FIR digital filters, parallel processing. Retiming: Definitions and properties, solving systems of inequalities, retiming techniques.

Unit II:

Unfolding: An algorithm for unfolding, properties and applications of unfolding. Folding: Folding transformation, register minimization techniques, folding of multirate systems

Fast Convolution: Introduction, Cook-Toom algorithm, Winograd algorithm, iterated convolution, cyclic convolution, design of fast convolution algorithm by inspection.

Unit IV:

Bit-Level Arithmetic Architectures: Introduction, parallel multipliers, bit-serial multipliers, bit serial filter design and implementation. Redundant Arithmetic: Introduction, redundant number representations, carry-free radix-2 addition and subtraction, radix-2 hybrid redundant multiplication architectures, data format conversion, redundancy to nonredundant converter.

Unit V:

Programmable Digital Signal Processors: Introduction, evolution of programmable digital signal processors, important features of DSP processors, DSP processors for mobile and wireless communications, processors for multimedia signal processing.

Text Book

1. Parhi, Keshab K. VLSI Digital Signal Processing Systems: Design and Implementation. Wiley, 1999.

Reference Books

1. V. K. Madisetti, VLSI Digital Signal Processors: An Introduction to Rapid Prototyping and Design Synthesis, IEEE Press, New York.
2. Meyer-Baese, Uwe. Digital Signal Processing with Field Programmable Gate Arrays. 4th ed., Springer, 2014.
3. S. Y. Kung, H. J. Whitehouse, VLSI and Modern Signal Processing, Prentice Hall.

Scripting Languages for Design Automation

M.Tech. I Year I Sem.

L T P C

Course Code:M25CS117

3 0 0 3

Course Overview:

This course introduces the use of scripting languages—PERL, TCL, and Python—in the context of Electronic Design Automation (EDA) workflows. Students will learn to write efficient automation scripts for parsing tool outputs, managing design files, and controlling EDA tools such as synthesis and simulation environments. The course emphasizes practical application, covering syntax, control structures, file I/O, regular expressions, and data processing. By the end of the course, learners will be able to automate common VLSI design tasks, improve productivity, and select the appropriate scripting language based on the use case.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Describe the role of scripting languages in EDA workflows and differentiate between scripting and compiled languages.
2. Write PERL scripts to perform text parsing, data extraction, and report generation.
3. Develop TCL scripts to automate tool commands and control design processes in EDA tools.
4. Construct Python scripts for file handling, data processing, and automation of design-related tasks.
5. Compare the features of PERL, TCL, and Python, and select suitable scripting languages for specific EDA applications.

Syllabus

Unit I:

Introduction to Scripting Languages in EDA: Introduction to scripting and automation, Scripting vs compiled languages, Using interpreters and writing first scripts in Perl, Tcl, and Python, Command-line execution, Variable types and assignments (overview), Control flow basics (if, loops – overview), Basic file I/O (overview), Importance of scripting in EDA tools and flows.

Unit II:

PERL Scripting: Scalar data, Arrays and list data, Hashes, Input and output, Control structures, Regular expressions, Pattern matching with regex, Substitution and translation, Using files and file handles, String manipulation, Subroutines, Using Perl modules, Command-line arguments and environment variables, Text parsing examples, Report generation

Unit III:

TCL Scripting: Tcl syntax and structure, Variables and data types, Lists and arrays, Expressions and operators, Control flow (if, switch, while, for, foreach), Procedures and variable scope, File input and output, String and list manipulation, Error handling, Working with commands and arguments, Tool-specific scripting conventions, Example tool scripts for synthesis and simulation

Unit IV:

Python for Design Automation and Data Processing: Python basics and data types, Expressions and operators, Flow control (if, for, while), Functions, Lists and dictionaries, String manipulation, File reading and writing, Pattern matching with regular expressions, Working with CSV and JSON files, Automating the keyboard and mouse, Using os, sys, and subprocess modules, Writing utility scripts for automation

Unit V:

Advanced Integration and Comparison: Comparison of PERL, TCL, and Python features, Strengths and weaknesses in EDA use-cases, Best practices for automation and maintainability, Calling external commands and shell integration in all three languages, Script interoperability using intermediate files (CSV, JSON), Efficiency, readability, and debugging considerations, Choosing the right scripting language for given EDA tasks

Text Books

1. Schwartz, Randal L., brian d foy, and Tom Phoenix. Learning Perl. 7th ed., O'Reilly Media, 2016.
2. Welch, Brent B., Ken Jones, and Jeffrey Hobbs. Practical Programming in Tcl and Tk. 4th ed., Prentice Hall, 2003.
3. Sweigart, Al. Automate the Boring Stuff with Python: Practical Programming for Total Beginners. 2nd ed., No Starch Press, 2019.

Reference Books

1. Robbins, Arnold. Scripting the UNIX System: Using Bash, Perl, and More. Addison-Wesley, 2003.
2. Ousterhout, John K. Tcl and the Tk Toolkit. 2nd ed., Addison-Wesley Professional, 2009.
3. Python Software Foundation. Python Language Reference Manual. <https://docs.python.org>.

CMOS Digital IC Design Laboratory

M.Tech. I Year I Sem.

Course Code: M25VL107

L T P C

0 0 4 2

Course Overview

This course provides a comprehensive introduction to CMOS digital circuit design, focusing on the fundamental building blocks such as inverters, combinational and sequential logic circuits, and their implementation strategies. Students will explore device physics, design techniques, timing analysis, and the impact of interconnect parasitics on circuit performance. Through practical experiments, learners gain hands-on experience in designing, simulating, and analyzing CMOS circuits, preparing them for advanced work in VLSI and digital IC design.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Design and analyze the static and dynamic behavior of CMOS inverters.
2. Implement and simulate basic CMOS combinational logic gates using various design styles.
3. Develop and verify sequential logic circuits such as latches and flip-flops.
4. Compare different CMOS design methodologies including custom, semi-custom, and array based approaches.
5. Evaluate the impact of interconnect parasitics on the performance and reliability of CMOS circuits.

List of Experiments (Minimum 12 Experiments)

1. Measure Voltage Transfer Characteristic (VTC) of CMOS Inverter: Design a static CMOS inverter and plot the input vs. output voltage to determine switching threshold and noise margins.
2. Determine Propagation Delay of CMOS Inverter: Apply a square wave input, simulate the output waveform, and measure the rise time, fall time, and propagation delay.
3. Design and Simulate CMOS NAND Gate: Implement a 2-input NAND gate using CMOS and verify its truth table and transient response.
4. Compare Static CMOS and Pass-Transistor NAND Gate: Design both logic styles for NAND gate, simulate output voltage levels, and compare delay and power.
5. Design a Dynamic CMOS NOR Gate: Create a dynamic NOR gate, simulate precharge and evaluation phases, and observe output waveform timing.
6. Implement and Simulate a Static SR Latch: Design an SR latch using CMOS transistors; verify bistability by applying input set/reset sequences.
7. Design a Master-Slave D Flip-Flop: Build a master-slave edge-triggered flip-flop, apply clock and data inputs, and verify timing and output behavior.
8. Compare Latch-Based and Register-Based Pipeline Stages: Design a simple 2-stage pipeline using latches and registers; simulate and compare data propagation delays.
9. Custom vs Standard Cell Design of a 2-Input AND Gate: Implement a 2-input AND gate using full custom transistor-level design and standard cell approach; compare layout area.
10. Array-Based Implementation of a 2-Bit Adder: Design a 2-bit adder using an array-based logic style; simulate functional correctness and evaluate area.
11. Analyze Delay Due to Capacitive Load on CMOS Inverter: Add different load capacitances to inverter output and simulate the resulting delay variation.
12. Effect of Interconnect Resistance on Signal Propagation: Model a resistive interconnect connected to a CMOS inverter output; simulate delay and signal attenuation.
13. Simulate Interconnect RC Parasitics Impact on Output Waveform: Extract parasitic RC values for a simple wire segment and simulate their effect on signal rise and fall times.
14. Compare Signal Integrity with and without Interconnect Inductance: Model a simple interconnect with inductance; simulate signal ringing and delay effects compared to purely RC models.

CMOS Analog IC Design Laboratory

M.Tech. I Year I Sem.

Course Code: M25VL108

L T P C

0 0 4 2

Course Overview:

This laboratory course complements the theory of analog CMOS design by providing hands-on experience with MOS device characterization, amplifier circuits, differential pairs, current mirrors, and operational amplifiers. Students will learn to design, simulate, and analyze fundamental analog building blocks using industry-standard tools. The experiments emphasize understanding device physics, circuit behavior, and performance trade-offs in real-time conditions, preparing students for practical analog integrated circuit design.

Course Outcomes (COs)

After successful completion of this laboratory course, students will be able to:

1. Design and simulate MOS transistors to analyse their electrical characteristics and model parameters.
2. Implement and evaluate single-stage amplifiers including common-source, source follower, and common-gate configurations.
3. Design differential amplifiers with resistive and active loads and measure their gain and common-mode rejection properties.
4. Develop basic, cascode, and active current mirrors, analysing their current replication and output impedance.
5. Design and analyse two-stage CMOS operational amplifiers focusing on gain, stability, and frequency response.

List of Experiments (Minimum 12 Experiments)

1. MOSFET I-V Characteristics Simulation: Design and simulate NMOS and PMOS transistors to plot I_D vs V_{DS} and I_D vs V_{GS} characteristics; analyze threshold voltage and saturation behavior.
2. Effect of Second-Order Parameters on MOS Device Performance: Simulate and study effects like channel length modulation, body effect, and velocity saturation on transistor I-V characteristics.
3. Extraction of MOS Device Model Parameters Using SPICE: Extract and verify MOSFET parameters (threshold voltage, mobility, etc.) from device simulation for different model levels.
4. Design and Simulation of Common-Source Amplifier with Resistive Load: Design a common-source amplifier and analyze voltage gain, input/output impedance, and frequency response.
5. Design and Simulation of Common-Source Amplifier with Diode-Connected Load: Implement a CS amplifier with diode-connected load and compare gain and linearity with resistive-load version.
6. Design and Analysis of Source Follower (Common-Drain) Amplifier: Build a source follower circuit; simulate and measure voltage gain, output impedance, and linearity.
7. Design and Simulation of Common-Gate Amplifier: Design a common-gate stage and analyze its input/output characteristics and high-frequency response.
8. Design of Basic Differential Pair with Resistive Load: Simulate a differential pair and analyze differential gain, common-mode gain, and calculate CMRR.
9. Differential Amplifier with MOS Current Mirror Load: Implement a differential pair with active current mirror load; analyze improvements in gain and CMRR.
10. Simulation of Gilbert Cell Mixer: Design a Gilbert cell circuit and simulate frequency mixing operation with two sinusoidal inputs.

11. Design and Simulation of Basic Current Mirror: Implement a basic current mirror; simulate output current accuracy and dependence on transistor sizing.
12. Design and Simulation of Cascode Current Mirror: Build a cascode current mirror; analyze output impedance and current matching improvement.
13. Design of Active Current Mirror Circuits: Implement Wilson or improved current mirrors; simulate and compare performance with basic and cascode types.
14. Design and Simulation of Two-Stage CMOS Operational Amplifier: Design a two-stage op-amp; analyze gain, phase margin, unity gain bandwidth, and frequency response.

Research Methodology and IPR

M.Tech. I Year I Sem.

Course Code: M25MB109

L T P C

2 0 0 2

Course Overview:

This course is designed to introduce students to the fundamental aspects of research methodology and intellectual property rights (IPR). It focuses on identifying and defining research problems, conducting effective literature reviews, writing technical reports and research proposals, and understanding the ethical aspects of research. The course also provides in-depth knowledge of intellectual property laws, including patents, copyrights, trademarks, and geographical indications. Students will learn the process of patenting, the global IPR scenario, and the importance of protecting innovations in a knowledge-driven economy.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Formulate research problems by identifying research gaps, objectives, and scope.
2. Analyse literature and research data while ensuring ethical standards and avoiding plagiarism.
3. Develop well-structured technical reports and research proposals using appropriate academic formats.
4. Evaluate types of intellectual property to determine suitable protection strategies for innovations.
5. Apply intellectual property rights concepts to emerging fields such as biotechnology, software, and traditional knowledge.

Syllabus

UNIT-I:

Meaning of research problem, Sources of research problem, Criteria Characteristics of a good research problem, Errors in selecting a research problem, Scope and objectives of research problem. Approaches of investigation of solutions for research problem, Data collection, Analysis, Interpretation, Necessary instrumentations.

UNIT-II:

Effective literature studies approaches, Analysis, Plagiarism, Research ethics.

UNIT-III:

Effective technical writing, how to write a report, paper in developing a research proposal, Format of research proposal, A presentation and assessment by a review committee.

UNIT-IV:

Nature of Intellectual Property: Patents, Designs, Trade and Copyright.

Process of Patenting and Development: Technological research, Innovation, Patenting, Development.

International Scenario: International cooperation on Intellectual Property, Procedure for grant of patents, Patenting under PCT.

UNIT-V:

Patent Rights: Scope of Patent Rights, Licensing and transfer of technology, Patent information and databases, Geographical Indications.

New Developments in IPR: Administration of Patent System, New developments in IPR, IPR of Biological Systems, Computer Software etc. Traditional knowledge, Case Studies, IPR and IITs.

Textbooks:

1. Melville, Stuart, and Wayne Goddard. Research Methodology: An Introduction for Science & Engineering Students.
2. Goddard, Wayne, and Stuart Melville. Research Methodology: An Introduction.

Reference Books:

1. Kumar, Ranjit. Research Methodology: A Step-by-Step Guide for Beginners. 2nd ed.
2. Halbert, Debora J. Resisting Intellectual Property. Taylor & Francis, 2007.
3. Mayall, W. H. Industrial Design. McGraw-Hill, 1992.
4. Niebel, Benjamin W. Product Design. McGraw-Hill, 1974.
5. Asimov, Morris. Introduction to Design. Prentice Hall, 1962.
6. Merges, Robert P., Peter S. Menell, and Mark A. Lemley. Intellectual Property in the New Technological Age. 2016.
7. Ramappa, T. Intellectual Property Rights under WTO. S. Chand, 2008.

Mixed Signal IC Design

M.Tech. I Year II Sem.

L T P C

Course Code: M25VL201

3 0 0 3

Course Overview:

This course provides a solid foundation in the analysis and design of mixed-signal integrated circuits (ICs), which combine analog and digital functionality on a single chip. It emphasizes signal theory, sampling methods, analog and digital filter design, and the architecture and analysis of data converters. Students will learn the fundamental concepts, mathematical tools, and circuit techniques needed to design real-world mixed-signal systems, with applications in communications, data acquisition, and signal processing.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Analyze sinusoidal signals and frequency-domain representations using Fourier tools and z transform methods.
2. Evaluate the effects of sampling, aliasing, and interpolation on analog signals and implement sample-and-hold circuits.
3. Design analog filters using active-RC, MOSFET-C, and gm-C topologies and interpret discrete-time filtering behavior.
4. Implement basic digital filters using FIR/IIR techniques and evaluate performance using DAC/ADC SPICE models.
5. Assess the performance of data converters based on quantization noise, SNR, and apply noise shaping methods to improve resolution.

Syllabus

Unit I:

Signals, Filters and Tools: Sinusoidal signals, in-phase and quadrature signals, the complex (z-) plane, comb filters – the digital comb filter, the digital differentiator, the digital integrator, representing signals – exponential Fourier series, Fourier transform, Dirac Delta function.

Unit II:

Sampling and Aliasing: Sampling – impulse sampling, decimation, the sample-and-hold (S/H), S/H spectral response, the reconstruction filter (RCF), circuit concerns for implementing the S/H, interpolation, Zero padding, Hold register, linear interpolation, K-path sampling – switched capacitor circuits, non-overlapping clock generation, implementing the S/H, the S/H with gain.

Unit III:

Analog Filters: Integrator building blocks – low pass filters, active-RC integrators, MOSFET-C integrators, gm-C (transconductance-C) integrators, discrete-time integrators, filtering topologies – the bilinear transfer function, the bquadratic transfer function Unit IV:

Digital Filters – SPICE models for DACs and ADCs, the ideal DAC, the ideal ADC, Sinc-shaped digital filters, band pass and high pass Sinc filters, interpolation using Sinc filters, filtering topologies – FIR filters, the bilinear transfer function, the bilinear transfer function.

Unit V:

Data Converters: Quantization noise, signal-to-noise ratio (SNR), clock jitter, improving SNR using averaging, the one-bit ADC and DAC, passive noise-shaping, improving SNR and linearity.

Text Books

1. R. Jacob Baker, CMOS Mixed-Signal Circuit Design, Second Edition, Wiley–IEEE Press, 2008.

Reference Books

1. Razavi, Behzad. Design of Analog CMOS Integrated Circuits. 2nd ed., McGraw-Hill Education, 2017.
2. Johns, David A., and Ken Martin. Analog Integrated Circuit Design. Wiley, 1997.
3. Sansen, Willy M.C. Analog Design Essentials. Springer, 2006.
4. Allen, Phillip E., and Douglas R. Holberg. CMOS Analog Circuit Design. 2nd ed., Oxford University Press, 2002.

FPGA Based System Design

M.Tech. I Year II Sem.

L T P C

Course Code: M25VL202

3 0 0 3

Course Overview:

This course introduces the principles and practices of FPGA-based system design, with a strong focus on digital logic implementation, system architecture, and modern design methodologies. Students will gain hands-on experience with hardware description languages, combinational and sequential logic design, and explore advanced topics such as platform FPGAs and multi-FPGA systems. The course equips learners with foundational knowledge and practical skills to architect, design, and optimize embedded digital systems using FPGAs. Suitable for postgraduate students in electronics, embedded systems, or VLSI design, this course bridges the gap between traditional digital logic design and modern reconfigurable computing.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Explain the architectural features and functional components of FPGA-based systems and describe their advantages in digital design applications.
2. Design combinational logic circuits using Verilog HDL and evaluate them for delay, power, and resource utilization on FPGA platforms.
3. Develop and simulate sequential logic circuits and finite state machines using appropriate design styles and clocking rules.
4. Apply behavioral design methodologies and demonstrate system modeling using HDLs in real world case studies.
5. Analyze and propose solutions for large-scale FPGA-based systems involving busses, platform FPGAs, and multi-FPGA architectures.

Syllabus

Unit I:

Introduction to FPGA-Based Systems: Introduction, basic concepts, digital design and FPGAs, FPGA-based system design, FPGA architectures, SRAM-based FPGAs, permanently programmed FPGAs, chip I/O, circuit design of FPGA fabrics, architecture of FPGA fabrics.

Unit II:

Combinational Logic Design in FPGAs: Introduction, the logic design process, hardware description languages -modeling with HDLs, Verilog, Combinational network delay, power and energy optimization, arithmetic logic, logic implementation for FPGAs, physical design for FPGAs, the logic design process revisited

Unit III:

Sequential Logic and State Machines: Introduction, the sequential machine design process, sequential design styles, rules for clocking, performance analysis, power optimization

Unit IV:

Design Methodologies and Behavioral Architecture: Introduction, behavioral design, design methodologies, design example

Unit V:

System-Level Design and Advanced FPGA Applications: Introduction, busses, platform FPGAs, multi-FPGA systems, Novel architectures

Text Books

1. Wolf, Wayne. FPGA-Based System Design. Pearson Education India, 2005.

Reference Books

1. Maxfield, Clive. The Design Warrior's Guide to FPGAs: Devices, Tools and Flows. Newnes, 1st ed., 2004.
2. Trimberger, Stephen M. Field-Programmable Gate Array Technology. Springer Science & Business Media, 2012.
3. Kuon, Ian, Russell Tessier, and Jonathan Rose. FPGA Architecture: Survey and Challenges. Now Publishers Inc., 2007.

VLSI Test and Testability

M.Tech. I Year II Sem.

Course Code: M25VL203

L T P C

3 0 0 3

Course Overview:

This course introduces students to digital system testing techniques and fault diagnosis in VLSI circuits. It covers fault models, test generation methods for combinational and sequential circuits, and various design-for-testability (DFT) strategies. Students will explore scan-based designs, Built In Self-Test (BIST) techniques, memory testing algorithms, and fault diagnosis methods. Emphasis is placed on practical testing challenges in digital and embedded systems to ensure reliability and fault tolerance.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Identify different types of faults in digital circuits and explain their corresponding logical fault models.
2. Apply test generation techniques to detect faults in combinational and sequential digital circuits.
3. Design scan-based and ad-hoc DFT architectures for improving circuit testability.
4. Implement Built-In Self-Test (BIST) strategies for digital systems and memory blocks.
5. Analyse fault diagnosis techniques to locate and interpret faults in logic-level digital circuits.

Syllabus

Unit-I:

Basics of Testing and Fault Modeling: Introduction to Testing - Faults in digital circuits - Modeling of faults - Logical Fault Models - Fault detection - Fault location - Fault dominance - Logic Simulation - Types of simulation - Delay models - Gate level Event-driven simulation.

Unit-II:

Test Generation for Combinational and Sequential Circuits: Test generation for combinational logic circuits - Testable combinational logic circuit design - Test generation for sequential circuits - design of testable sequential circuits. Design For Testability

Unit-III:

Design for Testability: Ad-hoc design - Generic scan-based design - Classical scan-based design – System level DFT approaches.

Unit-IV:

Self-Test and Test Algorithms: Built-In Self-Test - Test pattern generation for BIST - Circular BIST - BIST Architectures - Testable Memory Design - Test algorithms - Test generation for Embedded RAMs.

Unit-V:

Fault Diagnosis: Logic Level Diagnosis - Diagnosis by UUT reduction - Fault Diagnosis for Combinational Circuits - Self-checking

Text Books

1. Abramovici, M., M. A. Breuer, and A. D. Friedman. Digital Systems Testing and Testable Design. 1st ed., Jaico Publishing House, 2002.
2. Bushnell, M. L., and V. D. Agrawal. Essentials of Electronic Testing for Digital, Memory and Mixed-Signal VLSI Circuits. Illustrated ed., Springer Science & Business Media, 2006

Reference Books

1. Lala, P. K. Digital Circuit Testing and Testability. Academic Press, 2002.
2. Crouch, A. L. Design-for-Test for Digital IC's and Embedded Core Systems. 1st ed., Prentice Hall International, 1999

Physical Design Automation with AI

M.Tech. I Year II Sem.

L T P C

Course Code: M25VL204

3 0 0 3

Course Overview

This course introduces students to the fundamentals of VLSI physical design and explores how Artificial Intelligence (AI) is transforming Electronic Design Automation (EDA). Students will gain a comprehensive understanding of the VLSI design flow, physical design stages, partitioning algorithms, placement, routing, clock tree synthesis, and timing closure. The course also introduces the role of machine learning in optimizing physical design processes, covering key applications and challenges. Emphasis is placed on design rules, optimization techniques, and algorithmic approaches essential for real-world chip design.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Explain the physical design flow in VLSI and apply basic graph algorithms used in EDA tools.
2. Demonstrate understanding of chip planning techniques including floor planning, placement, and routing.
3. Analyze and implement routing strategies and clock tree synthesis for efficient signal distribution.
4. Evaluate timing closure techniques to ensure performance and reliability in VLSI designs.
5. Identify and discuss the applications and limitations of machine learning in physical design automation.

Syllabus

Unit I:

Introduction to Physical Design and AI in EDA: Introduction - Electronic Design Automation (EDA), VLSI Design Flow, VLSI Design Styles, Layout Layers and Design Rules, Physical Design optimizations, Algorithms and Complexity, Graph Theory Terminology, Common EDA Terminology. Netlist and System Partitioning– Introduction, KL and FM Algorithms, Multilevel Partitioning.

Unit-II:

Chip Planning and Placement: Introduction, optimization goals, floorplan representations, floor planning algorithms, pin assignment, power and ground routing. Global placement, legalization and detailed placement.

Unit-III:

Routing and Clock Tree Synthesis: Introduction, optimization goals, representations of routing regions, the global routing flow, single-net and full-net routing, detailed routing – horizontal and vertical constraint graphs, channel and switchbox routing, area routing, clock routing, modern clock tree synthesis.

Unit – IV:

Timing Closure: Timing analysis, and performance constraints, timing-driven placement, timing driven routing, physical synthesis, performance-driven design flow.

Unit-V:

Machine Learning in Physical Design: Introduction ML promises and challenges in physical design, Canonical ML applications, the state of ML for physical design.

Text Book

1. Kahng, Andrew B., et al. VLSI Physical Design: From Graph Partitioning to Timing Closure. 2nd ed., Springer International Publishing, 2022.
2. Sherwani, Naveed A. Algorithms for VLSI Physical Design Automation. 3rd ed., Springer, 2012.

Reference Books

1. Hsiao, Michael. Machine Learning Applications in Electronic Design Automation. Morgan & Claypool, 2020.
2. Cong, Jason, and Bei Yu. Machine Learning and AI for EDA: From Fundamentals to Advanced Applications. Springer, 2022.

Functional Verification using System Verilog and UVM

M.Tech. I Year II Sem.

L T P C

Course Code: M25VL205

3 0 0 3

Course Overview

This course provides a comprehensive introduction to functional verification using System Verilog and the Universal Verification Methodology (UVM). Starting with foundational System Verilog language constructs and object-oriented programming, the course gradually introduces advanced verification concepts including randomization, coverage, and inter-process communication. Building on this foundation, students learn the UVM framework for creating reusable and scalable testbenches, focusing on UVM components, sequences, transactions, and transaction-level modeling (TLM). Hands-on exercises and real-world examples solidify understanding, preparing students for practical verification challenges in ASIC and FPGA design environments. Course Outcomes (COs)

By the end of this course, students will be able to:

1. Write basic System Verilog testbenches using data types, control statements, and functions.
2. Use object-oriented programming and randomization to create flexible and reusable testbenches.
3. Measure verification quality using functional coverage in System Verilog.
4. Build UVM testbenches using components like tests, drivers, monitors, and agents.
5. Use UVM sequences and communication ports to send transactions and collect results.

Syllabus

Unit I:

System Verilog Fundamentals: Verification Guidelines – Introduction, verification process, basic testbench functionality, testbench components, simulation environment phases, testbench performance. Data Types – built-in data types, arrays, linked lists, creating new types and user defined structures, constants, strings. Procedural Statements and Routines – tasks, functions, and void functions, routine arguments, returning from a routine. Local data storage, time values.

Unit II:

Testbench and OOP Concepts: Connecting the Testbench and Design–separating the testbench and design, the interface construct, stimulus timing, interface driving and sampling, connecting it all together, program-module interactions, System Verilog assertions. Basic OOP – define a class, creating new objects, object deallocation, class routines, dynamic objects, copying objects, building a testbench. Randomization – Introduction, randomization in System Verilog, constraint details, solution probabilities, valid and in-line constraints, iterative and array constraints, random control, random generators, random device configuration.

Unit-III:

Advanced Concepts for UVM Readiness: Threads and Interprocess Communication – working with threads, interprocess communication, events, semaphores, mailboxes, building testbench with threads and IPC. Advanced OOP and Testbench Guidelines – inheritance, factory patterns, type casting and virtual methods, composition, inheritance, and alternatives, copying an object, callbacks. Functional Coverage – coverage types, strategies, anatomy of a cover group, triggering, data sampling, cross coverage.

Unit-IV:

UVM Infrastructure: Introduction, UVM Components, UVM Tests, UVM Transactions, UVM Sequences

Unit-V:

UVM Integration & TLM (Transaction-Level Modeling) Communication: UVM Agents,
Using Analysis Ports in a Testbench, Put and Get Ports in Action, UVM Reporting

Text Book

1. Spear, Chris. System Verilog for Verification: A Guide to Learning the Testbench Language Features. 2nd ed., Springer, 2014.
2. Salemi, Ray. UVM Primer: A Step-by-Step Introduction to the Universal Verification Methodology. Mentor Graphics, 2014.

Reference Books

1. Mathur, Ashok B. Advanced Functional Verification: Concepts and Techniques. Springer, 2021.
2. Bhasker, J., and Rakesh Chadha. System Verilog for Verification: A Guide to Learning the Testbench Language Features. Prentice Hall, 2007.
3. Bergeron, Janick. System Verilog for Verification: A Guide to Learning the Testbench Language Features. 3rd ed., Springer, 2012.

Low Power VLSI Design

M.Tech. I Year II Sem.

L T P C

Course Code: M25VL206

3 0 0 3

Course Overview

This course focuses on the principles and techniques for designing energy-efficient CMOS VLSI circuits. Students will learn about the sources and modeling of power dissipation in modern integrated circuits, and methods for estimating and optimizing power consumption at various design levels. Topics include low-power design strategies at the device, circuit, logic, architecture, and software levels. The course also explores emerging techniques like adiabatic computing, pass transistor logic, and asynchronous circuit design for ultra-low-power applications.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Identify sources of power dissipation in CMOS circuits and explain methods to reduce them.
2. Apply power estimation techniques to evaluate energy usage in combinational and sequential logic circuits.
3. Use architectural and circuit-level transformations to optimize designs for low power consumption.
4. Design and test low-voltage CMOS circuits considering submicron effects and leakage currents.
5. Explore and apply advanced low-power techniques such as adiabatic logic and software-level power optimization.

Syllabus

Unit I:

Low-Power CMOS VLSI Design: Introduction, Sources of Power Dissipation, Designing for Low Power. Physics of Power Dissipation in CMOS FET Devices- MIS structure, Long Channel and Sub-micron MOSFET, Gate Induced Drain Leakage, Power dissipation in CMOS-Short Circuit and Dynamic Dissipation, Load Capacitance.

Unit II:

Power Estimation in CMOS Circuits: Modelling of signals, Signal Probability Calculation, Probabilistic Techniques for Signal Activity Estimation. Statistical Techniques -Estimating Average Power in Combinational and Sequential Circuits, Estimation of Glitching Power, Power Estimation using Input Vector Compaction, Power Dissipation in Domino CMOS.

Unit III:

Synthesis for Low Power: Behavioural Level Transforms - Algorithm Level Transforms, Power Constrained Least Squares Optimization for Adaptive and Non-adaptive Filters, Circuit Activity Driven Architectural Transformations, Architecture Driven Voltage Scaling, Power Optimization using Operation Reduction and Substitution, Precomputation-Based Optimization for Low Power, Logic and Circuit Level Optimization for Low Power.

Unit IV:

Design and Test of Low Voltage CMOS Circuits: Introduction, Circuit Design Styles, Leakage Current in Deep Sub-micrometer Transistors, Deep Sub-micrometer Device Design Issues, Minimizing Short Channel Effect, Low Voltage Circuit Design Techniques – Reverse Vgs, Steeper Subthreshold Swing, Multiple Threshold Voltages, Multiple Supply Voltages.

Unit V:

Advanced Techniques: Adiabatic Computation, Pass Transistor Logic Synthesis, Asynchronous Circuits. Software Design for Low Power: Introduction, Sources of Software Power Dissipation, Software Power Estimation and Optimization.

Text Book

1. Roy, Kaushik, and Sharat C. Prasad. Low-Power CMOS VLSI Circuit Design. Wiley-IEEE Press, 2000.
2. Rabaey, Jan M., Anantha Chandrakasan, and Borivoje Nikolic. Digital Integrated Circuits: A Design Perspective. 2nd ed., Prentice Hall, 2003.

Reference Books

1. Chandrakasan, Anantha P., and Robert W. Brodersen. Low Power Digital CMOS Design. Kluwer Academic Publishers, 1995.
2. Pedram, Massoud. Power-Aware Design Methodologies. Springer, 2005.

Microchip Fabrication Techniques

M.Tech. I Year II Sem.

L T P C

Course Code: M25VL207

3 0 0 3

Course Overview

This course provides a comprehensive introduction to the principles and processes involved in semiconductor fabrication, focusing on silicon-based microchip manufacturing. Students will explore the semiconductor industry, material properties, and crystal growth techniques essential for wafer preparation. The course covers wafer fabrication methods, contamination control, and yield optimization. Key lithography and patterning techniques, including advanced photolithography, doping, and thin-film deposition, are studied in detail. Finally, metallization, device evaluation, packaging, and the business aspects of wafer fabrication complete the curriculum, preparing students for roles in VLSI fabrication and semiconductor manufacturing industries.

Course Outcomes:

By the end of this course, students will be able to:

1. Describe the semiconductor industry landscape and explain the properties of semiconductor materials and wafer preparation techniques.
2. Outline the wafer fabrication process and apply contamination control and productivity improvement methods.
3. Demonstrate understanding of lithography and patterning processes used in semiconductor manufacturing.
4. Explain advanced lithography techniques, doping processes, and thin-film deposition methods for device fabrication.
5. Analyze metallization techniques, device evaluation procedures, packaging methods, and the business considerations of wafer fabrication.

Syllabus

Unit-I:

Semiconductor Industry and Materials: The Semiconductor Industry, Properties of Semiconductor Materials and Chemicals, Crystal Growth and Silicon Wafer Preparation

Unit-II:

Wafer Fabrication and Contamination Control: Overview of Wafer Fabrication, Contamination Control, Productivity and Process Yields, Oxidation

Unit-III:

Lithography Processes – Patterning Steps: The Ten-Step Patterning Process — Surface Preparation to Exposure, The Ten-Step Patterning Process — Developing to Final Inspection

Unit-IV:

Advanced Lithography, Doping, and Deposition: Advanced Photolithography Processes, Doping, Layer Deposition

Unit-V:

Metallization, Device Evaluation, Business, and Packaging: Metallization, Process and Device Evaluation, The Business of Wafer Fabrication, Introduction to Devices and Integrated Circuit Formation, Introduction to Integrated Circuits, Packaging

Text Books

1. Van Zant, Peter. Microchip Fabrication: A Practical Guide to Semiconductor Processing. 6th ed., McGraw-Hill, 2014.

Reference Books

1. Ghandhi, Sorab K. VLSI Fabrication Principles: Silicon and Gallium Arsenide. 2nd ed., Wiley, 1994.
2. Sze, Simon M., and Kwok K. Ng. Physics of Semiconductor Devices. 3rd ed., WileyInterscience, 2006.
3. Streetman, Ben G., and Sanjay Banerjee. Solid State Electronic Devices. 7th ed., Pearson, 2014.
4. Wolf, Stephen, and Richard N. Tauber. Silicon Processing for the VLSI Era. Vol. 1, Lattice Press, 1986.

Power Management IC Design

M.Tech. I Year II Sem.

L T P C

Course Code: M25VL208

3 0 0 3

Course Overview

This course provides a comprehensive understanding of modern Power Management Integrated Circuits (PMICs), emphasizing the principles, design methodologies, and implementation challenges across various topologies such as linear regulators, inductive converters, and switched capacitor converters. Through theoretical analysis and practical case studies (e.g., smartphones and IoT), students will develop skills to design energy-efficient, high-performance power management solutions suited for SoCs and complex embedded systems. The course also includes peripheral circuit design for sensing, protection, and control integration.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Describe the roles, architectures, and functional requirements of Power Management ICs (PMICs) and their application in modern electronic systems.
2. Design linear voltage regulators, including advanced and digital LDOs, considering efficiency, stability, and transient performance.
3. Analyse inductive DC-DC converter topologies (buck, boost, buck-boost, multi-phase, SIMO) with emphasis on performance metrics and control techniques.
4. Implement switched capacitor and charge pump converters for integrated, compact, and efficient power management solutions.
5. Integrate gate driver circuits, protection mechanisms, and sensing modules to ensure reliability and safety in PMICs.

Syllabus

Unit-I:

Fundamentals of Power Management ICs: Role and requirements of Power Management ICs (PMICs), the smartphone as a typical example, fundamental concepts - linear regulator, the inductive DC-DC converter, the Switched capacitor converters, the hybrid converter, power delivery - lateral and vertical, integrated voltage regulator (IVR), dynamic voltage and frequency scaling (DVFS).

Unit-II:

Linear Voltage Regulators: Fundamental circuit and control concept, drop voltage and power efficiency, frequency behavior and stability, fast transient techniques and slew-rate enhancement, PSRR, output noise, soft-start, Advanced LDO types: capacitor-less, flipped voltage follower, Digital LDOs: ADC, digital controller, limit cycle oscillations.

Unit-III:

Inductive DC-DC Converters: The fundamental Buck converter, voltage conversion ratio, ripple, losses and power conversion efficiency, inductor and capacitor sizing, voltage-mode and current mode control, Loop compensation: Type I, II, III compensators, Constant on-time and hysteretic control, DCM operation and burst mode, Boost, buck-boost, and flyback converters, Multi-phase converters: ripple cancellation, phase shedding, Single inductor multiple output (SIMO) converters.

Unit-IV:

Switched-Capacitor (SC) and Charge Pump Converters: Basic operation of charge pumps: diode-based and transistor-based, Parasitic effects, charge sharing, and efficiency, SC converter topologies: Dickson, ladder, Fibonacci, Charge flow modeling and output resistance, Gate drive techniques, Capacitor and switch sizing, multi-phase and multi-ratio SC converters, interleaving, ripple reduction, and closed-loop control.

Unit-V:

Gate Drivers, Protection, and Sensing: Gate driver architectures: CMOS inverters, cascaded drivers, Bootstrap techniques and dv/dt triggering, Level shifters: resistor-based, cross-coupled, capacitive, Current sensing methods: shunt, replica, DCR, Protection circuits: OVP, thermal shutdown, UVLO, power-on-reset, Bandgap reference circuits and trimming, Zero-cross detection and current limiting.

Text Books

1. Wicht, Bernhard. Design of Power Management Integrated Circuits. Wiley, 2024.

Reference Books

1. Erickson, Robert W., and Dragan Maksimovic. Fundamentals of Power Electronics. 2nd ed., Springer, 2001.
2. Basso, Christophe. Switch-Mode Power Supplies: SPICE Simulations and Practical Designs. McGraw-Hill Education, 2008.
3. Wu, Jinrong, and Ray Ridley. Power Supply Design: A Practical Guide. Springer, 2019.

Mixed Signal IC Design Laboratory

M.Tech. I Year II Sem.
Course Code: M25VL209

L T P C
0 0 4 2

Course Overview

This course introduces the fundamental concepts of signal processing and filter design, focusing on both analog and digital domains. Students will explore signal representation, sampling theory, aliasing, and various filtering techniques including analog integrators, digital filters, and data converters. The course combines theoretical knowledge with practical experiments to develop skills in designing, simulating, and analyzing signal processing circuits and systems.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Analyze and represent signals using sinusoidal components and the complex z-plane.
2. Design and evaluate sample-and-hold circuits and interpolation techniques to mitigate aliasing effects.
3. Implement and analyze analog filter circuits including active-RC, MOSFET-C, and gm-C integrators.
4. Design and simulate digital filters such as comb, Sinc-shaped, and FIR filters using bilinear transform methods.
5. Model and evaluate the performance of data converters including ideal DACs and ADCs.

List of Experiments (Minimum 12 Experiments)

1. Sinusoidal Signals and Quadrature Components: Generate and analyze sinusoidal signals including their in-phase and quadrature components to understand signal representation.
2. Signal Representation on Complex (z-) Plane: Plot signals on the complex z-plane and analyze their magnitude and phase characteristics.
3. Digital Comb Filter Design: Design and simulate a digital comb filter and analyze its frequency response to understand notch filtering.
4. Digital Differentiator and Integrator: Implement digital differentiator and integrator circuits and analyze their time and frequency domain responses.
5. Impulse Sampling and Aliasing Analysis: Simulate impulse sampling and study the aliasing effect in the frequency spectrum of the sampled signal.
6. Sample-and-Hold (S/H) Circuit Analysis: Design a sample-and-hold circuit and analyze its spectral response and effect on signal reconstruction.
7. Interpolation Techniques: Implement zero padding and linear interpolation methods on sampled data to improve signal resolution.
8. Switched-Capacitor Sample-and-Hold Circuit: Design a switched-capacitor sample-and hold circuit with non-overlapping clocks and analyze its performance.
9. Active-RC Low-Pass Integrator Design: Design and simulate an active-RC low-pass integrator filter and analyze its frequency response.
10. MOSFET-C and gm-C Integrator Design: Implement MOSFET-C and gm-C integrators, compare their characteristics and frequency response.
11. Discrete-Time Integrator Design: Design and analyze discrete-time integrator circuits to understand their filtering behavior.
12. Ideal DAC and ADC Modeling: Model ideal DAC and ADC circuits, and analyze their input output characteristics and linearity.

13. Sinc-Shaped Digital Filter Design: Design Sinc-shaped digital filters including bandpass and high pass filters and analyze their frequency response.
14. FIR Filter Implementation Using Bilinear Transfer Function: Implement FIR filters using the bilinear transfer function and analyze filter characteristics like gain and phase response.

FPGA Based System Design Laboratory

M.Tech. I Year II Sem.

L T P C

Course Code: M25VL210

0 0 4 2

Course Overview

This laboratory course focuses on practical hands-on experience with FPGA design and implementation using Hardware Description Languages (HDLs) such as Verilog or VHDL. Students will learn to design, simulate, and implement fundamental digital building blocks, combinational and sequential circuits, and complex systems like finite state machines and communication modules on FPGA platforms. The course covers a range of topics from basic logic gates and arithmetic units to real-time systems and digital signal processing applications. Emphasis is placed on simulation, verification, and hardware validation to bridge the gap between theoretical concepts and real-world digital system design.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Write and simulate HDL code for basic combinational and sequential digital circuits using Verilog HDL.
2. Design and implement complex digital systems such as FSMs, arithmetic logic units, and communication modules on FPGA platforms.
3. Develop and verify interfacing protocols for external hardware devices like seven-segment displays, keypads, and UART communication.
4. Apply design methodologies for timing, synchronization, and resource optimization in FPGA based digital system design.
5. Demonstrate the ability to deploy and debug digital designs on FPGA development boards, validating functionality through hardware testing

List of Experiments (Any 12 Experiments)

1. LED Blinking Using Verilog: Implement a basic LED blink circuit to understand FPGA programming and output pin control.
2. Design and Simulation of Basic Logic Gates using Verilog HDL: To write HDL code for basic logic gates (AND, OR, NOT, XOR), simulate their functionality, and verify the outputs using a waveform viewer.
3. Implementation of 4-bit Adder/Subtractor on FPGA: To design and implement a 4-bit adder/subtractor using Verilog, simulate and verify functionality on an FPGA development board.
4. Design of a 4x1 Multiplexer and 1x4 Demultiplexer: To write and simulate Verilog code for a 4x1 MUX and 1x4 DEMUX and validate outputs through FPGA implementation.
5. Comparator Design (2-bit or 4-bit): Design a simple digital comparator circuit that compares two binary inputs.
6. Design and Implementation of a 4-bit Synchronous Counter: To implement a 4-bit up/down synchronous counter using HDL, simulate for timing and logic correctness, and deploy it on FPGA hardware.
7. Finite State Machine (FSM) Design: Sequence Detector-To design a Moore or Mealy FSM for sequence detection, simulate the state transitions, and implement the design on an FPGA board.
8. Design and Implementation of an ALU Supporting Basic Operations: To design an Arithmetic Logic Unit that performs basic arithmetic and logic functions (ADD, SUB, AND, OR, NOT) and test it on FPGA.
9. Interfacing Seven Segment Display with FPGA: To write HDL code to drive a seven segment display with binary or BCD inputs and implement the interface on FPGA hardware.
10. Shift Register (Left/Right): Design a shift register that shifts input bits left or right on each clock pulse.

11. Implementation of Traffic Light Controller using FSM on FPGA: To design a traffic light controller using finite state machines, simulate its time sequence, and implement it on FPGA hardware.
12. PWM Signal Generation using FPGA: To implement a pulse-width modulation (PWM) generator using Verilog HDL and demonstrate its use in applications like LED brightness control.
13. Real-Time Clock Design and Display using FPGA: To implement a real-time clock on FPGA with hour-minute-second display and use multiplexed seven-segment display for output.
14. Serial Input with UART Receiver (Basic): Implement a simple UART receiver to receive serial data and blink an LED.
15. Implementing Digital Filters (FIR/IIR) on FPGA: To implement a basic Finite Impulse Response (FIR) or Infinite Impulse Response (IIR) filter in HDL and simulate its output for given inputs.

CMOS RF IC Design**M.Tech. II Year I Sem.****L T P C****Course Code: M25VL301****3 0 0 3****Course Overview**

This course introduces the principles and design methodologies of CMOS Radio Frequency Integrated Circuits (RFICs). Students will learn to design and analyse critical RF building blocks such as low-noise amplifiers (LNAs), mixers, oscillators, and phase-locked loops (PLLs) in CMOS technology. Emphasis is placed on RF system-level understanding, noise and nonlinearity modeling, frequency planning, matching networks, and CMOS implementation strategies. The course combines theory, design practice, and simulation insights essential for modern wireless and communication IC design.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Analyse RF system-level parameters such as gain, noise figure, and non-linearity using standard performance metrics.
2. Design CMOS small-signal amplifier circuits, including LNAs, with appropriate impedance matching and noise optimization techniques.
3. Implement CMOS oscillator circuits such as LC and ring oscillators with attention to phase noise and frequency stability.
4. Evaluate the performance of CMOS mixer circuits focusing on frequency conversion efficiency, linearity, and noise behaviour.
5. Apply the principles of PLLs and frequency synthesizers to develop CMOS-based frequency generation solutions for RF systems.

Syllabus**Unit I:**

Introduction to RF Design and CMOS Technology: Review of RF system fundamentals - system gain, noise figure, nonlinearities, and link budget. Review of CMOS technology, basic MOSFET RF equivalent circuit model, advanced MOSFET RF equivalent circuit model, SPICE modeling of CMOS RF circuits – SPICE level 3 and BSIM parameters.

Unit II:

Small-Signal MOS Amplifier for RF: Basic amplifying structure, improvements to the basic amplifying structure, amplifier matching (LC and inductive), low-noise amplifiers (LNAs) – noise modeling for common source and common gate LNAs.

Unit III:

CMOS Oscillator Circuits: Review of general feedback principles, fixed-frequency oscillators, ring oscillator, voltage control of oscillators, oscillator phase noise and estimation.

Unit IV:

CMOS Mixer Circuits: General mixer concepts, single MOS mixer topologies, balanced MOSFET mixers, image rejection circuit topologies, I/Q mixer topologies.

Unit V:

CMOS PLLs and Frequency Synthesizers: Introduction to the phase lock loop – definitions and basic operation, phase detection and phase-frequency detection, loop filters, PLL noise behaviour, PLL behavioural modeling. Frequency Synthesis – PLL-based synthesizers, direct digital synthesis.

Text Book

1. Robert H. Caverly, CMOS RFIC Design Principles, Artech House, 2016.

Reference Books

1. Thomas H. Lee, The Design of CMOS Radio-Frequency Integrated Circuits, Cambridge University Press, 2nd Edition.
2. Behzad Razavi, RF Microelectronics, Prentice Hall, 2nd Edition.
3. R. Jacob Baker, CMOS: Circuit Design, Layout, and Simulation, Wiley IEEE Press, 3rd Edition.
4. Ali M. Niknejad, RF CMOS: Modeling and Technology for Wireless Design, Cambridge University Press.
5. David M. Pozar, Microwave Engineering, Wiley, 4th Edition.

Hardware Security in VLSI Design

M.Tech. II Year I Sem.

L T P C

Course Code: M25VL302

3 0 0 3

Course Overview

This course provides an in-depth understanding of security challenges and vulnerabilities in modern VLSI systems, particularly within SoC and PCB designs. Students will learn about hardware threats such as Trojans, reverse engineering, IP piracy, side-channel attacks, test-oriented and physical attacks, and how to design secure hardware using primitives like PUFs and TRNGs. Through a mix of theoretical foundations and hands-on experimentation, students will be equipped to identify, analyse, and mitigate hardware security threats in real-world VLSI systems.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Identify and explain the key layers and components of VLSI systems vulnerable to hardware attacks.
2. Analyse different types of hardware Trojans and IP piracy techniques and suggest appropriate countermeasures.
3. Evaluate side-channel and test-oriented attacks on SoC and FPGA-based systems using suitable models.
4. Demonstrate an understanding of physical attacks and PCB vulnerabilities through attack modeling and analysis.
5. Design and implement hardware security primitives such as PUFs and TRNGs to protect VLSI designs from cloning and counterfeiting.

Syllabus

Unit I

Introduction to Hardware Security: Overview of a computing system, layers of a computing system, hardware security vs. hardware trust, attacks, vulnerabilities and countermeasures, conflict between security and test/debug, evolution of hardware security, overview of electronic hardware – nanoscale technologies, ASICs and FPGAs, printed circuit board, embedded systems, hardware firmware-software interaction.

Unit II:

Hardware Trojans: Introduction, SoC design flow, hardware trojans, hardware trojans in FPGA designs, hardware trojans taxonomy, trust benchmarks, countermeasures against hardware trojans, hardware trojan attacks. Hardware IP Piracy and Reverse Engineering: Introduction, hardware intellectual property (IP), security issues in IP-based SoC design, security issues in FPGA, reverse engineering and tampering.

Unit III:

Side-Channel Attacks: Introduction, taxonomy of side-channel attacks, uncommon side-channel attacks, power analysis attacks, electromagnetic (EM) side-channel attacks, fault-injection attacks, timing attacks. Test-Oriented Attacks: Introduction, scan-based attacks, JTAG-based attacks.

Unit IV:

Physical Attacks and Countermeasures: Introduction, reverse engineering, probing attack. Attacks on PCB: Security challenges, attack models, bus snooping attack.

Unit-V:

Hardware Security Primitives: Introduction, physical unclonable functions (PUFs), true random number generator (TRNG), design of anti-counterfeit, existing challenges and attacks. Security and Trust Assessment: Security assets and attack models, pre-silicon and post-silicon security and trust assessment.

Text Book

1. Bhunia, Swarup, and Mark M. Tehranipoor. Hardware Security: A Hands-on Learning Approach. 1st ed., Academic Press, 2019.

Reference Books

1. Tehranipoor, Mark, and Cliff Wang, editors. Introduction to Hardware Security and Trust. Springer, 2012.
2. Bhunia, Swarup, and Sandip Ray. Fundamentals of IP and SoC Security: Design, Verification, and Debug. Springer, 2017.
3. Wolf, Marilyn. Embedded System Interfacing: Design for the Internet-of-Things (IoT). Morgan Kaufmann, 2019.
4. Skorobogatov, Sergei. Semi-Invasive Attacks: A New Approach to Hardware Security Analysis. Springer, 2007.

Advanced Memory Design and Architectures

M.Tech. II Year I Sem.

L T P C

Course Code: M25VL303

3 0 0 3

Course Overview

This course provides an in-depth exploration of memory systems and architectures in modern and next-generation computer systems. Starting from the foundational concepts of caching and memory hierarchy, the course advances through on-chip network design, multicore memory consistency, DRAM system architectures, and emerging non-volatile memory technologies. It emphasizes architectural modeling, performance optimization, and system-level design trade-offs relevant to current and future computing platforms, including those used in high-performance and embedded systems.

Course Outcomes (COs)

By the end of this course, students will be able to:

1. Describe the structure, operation, and performance aspects of cache memory systems, including advanced designs like trace caches and prefetching.
2. Analyse the architecture and performance of on-chip networks (NoCs), including routing mechanisms and router design.
3. Explain memory models, identify data races, and apply concepts like transactional memory in multicore systems.
4. Illustrate the organization and timing of DRAM systems and evaluate the role of memory controllers.
5. Compare various emerging memory technologies and recommend suitable types for specific system-level applications

Syllabus

Unit I:

Caches: Memory hierarchy and the notion of caches, virtual memory, modeling and designing a cache, advanced cache design, trace caches, instruction prefetching, data prefetching.

Unit II:

The On-chip Network: Overview of an NoC, message transmission, routing, design of a router, non-uniform cache architectures, performance aspects.

Unit III:

Multicore Systems: Parallel programming, issues in parallel hardware, theoretical foundations of memory models, memory models, data races, transactional memory.

Unit IV:

DRAMs: DRAM cell, capacitors used in DRAM cells, array of DRAM cells, a computer system with DRAM arrays, design spaces of DRAMs, DDR generations and timing, buffered DIMMs, DRAM access protocols, DRAM timing, memory controller.

Unit V:

Emerging Memory Technologies: Flash memory, ferroelectric RAM (FeRAM), magneto resistive RAM (MRAM), phase change memory (PCM), resistive RAM (ReRAM), 3D and embedded memory technologies.

Text Book

1. Sarangi, Smruti R. Next-Gen Computer Architecture: Till the End of Silicon. Version 3.1, Smruti R. Sarangi, 2023.

Reference Books

1. Jacob, Bruce, Spencer W. Ng, and David T. Wang. Memory Systems: Cache, DRAM, Disk. Morgan Kaufmann, 2008.
2. Sharma, Ashok K. Semiconductor Memories: Technology, Testing, and Reliability. Wiley IEEE Press, 1997.
3. Hennessy, John L., and David A. Patterson. Computer Architecture: A Quantitative Approach. 6th ed., Morgan Kaufmann, 2019.
4. Keeth, Brent, et al. DRAM Circuit Design: Fundamental and High-Speed Topics. Wiley-IEEE Press, 2007.

Business Analytics (Open Elective)

M.Tech. I Year II Sem.

Course Code: M25MB309

Prerequisite: None

L T P C

3 0 0 3

Course objectives:

- Understand the role of business analytics within an organization.
- Analyze data using statistical and data mining techniques and understand relationships between the underlying business processes of an organization.
- To gain an understanding of how managers use business analytics to formulate and solve business problems and to support managerial decision making.
- To become familiar with processes needed to develop, report, and analyze business data.
- Use decision-making tools/Operations research techniques.
- Manage business process using analytical and management tools.
- Analyze and solve problems from different industries such as manufacturing, service, retail, software, banking and finance, sports, pharmaceutical, aerospace etc.

Course Outcomes:

- Students will demonstrate knowledge of data analytics.
- Students will demonstrate the ability of think critically in making decisions based on data and deep analytics.
- Students will demonstrate the ability to use technical skills in predicative and prescriptive modeling to support business decision-making.
- Students will demonstrate the ability to translate data into clear, actionable insights.

UNIT- I

Business analytics: Overview of Business analytics, Scope of Business analytics, Business Analytics Process, Relationship of Business Analytics Process and organization, competitive advantages of Business Analytics. Statistical Tools: Statistical Notation, Descriptive Statistical methods, Review of probability distribution and data modelling, sampling and estimation methods overview.

UNIT- II

Trendiness and Regression Analysis: Modelling Relationships and Trends in Data, simple Linear Regression. Important Resources, Business Analytics Personnel, Data and models for Business analytics, problem solving, Visualizing and Exploring Data, Business Analytics Technology.

UNIT- III

Organization Structures of Business analytics, Team management, Management Issues, Designing Information Policy, Outsourcing, Ensuring Data Quality, measuring contribution of Business analytics, Managing Changes. Descriptive Analytics, predictive analytics, predicative Modelling, Predictive analytics analysis, Data Mining, Data Mining Methodologies, Prescriptive analytics and its step in the business analytics Process, Prescriptive Modelling, nonlinear Optimization.

UNIT- IV

Forecasting Techniques: Qualitative and Judgmental Forecasting, Statistical Forecasting Models, Forecasting Models for Stationary Time Series, Forecasting Models for Time Series with a Linear Trend, Forecasting Time Series with Seasonality, Regression Forecasting with Casual Variables, Selecting Appropriate Forecasting Models. Monte Carlo Simulation and Risk Analysis: Monte Carle Simulation Using Analytic Solver Platform, New-Product Development Model, Newsvendor Model, Overbooking Model, Cash Budget Model.

UNIT- V

Decision Analysis: Formulating Decision Problems, Decision Strategies with the without Outcome Probabilities, Decision Trees, The Value of Information, Utility and Decision Making. Recent Trends in Embedded and collaborative business intelligence, Visual data recovery, Data Storytelling and Data journalism.

TEXT BOOKS:

1. Business analytics Principles, Concepts, and Applications by Marc J. Schniederjans, Dara G. Schniederjans, Christopher M. Starkey, Pearson FT Press.
2. Business Analytics by James Evans, persons Education.

Industrial Safety (Open Elective)

M.Tech. I Year II Sem.

L T P C

Course Code: M25VL305

3 0 0 3

Course Objectives:

- To provide information regarding different elements of industrial water pollution and Methods of treatment.
- To expose to the various industrial applications, maintenance, preventive measures taken against wear and tear.

Course Outcomes: At the end of the course, student will be able to:

- Know how to take safety measures in executing works
- Identify the need for maintenance (or) replacement of equipment
- Understand the need for periodic and preventive maintenance

UNIT- I

Industrial safety: Accident, causes, types, results and control, mechanical and electrical hazards, types, causes and preventive steps/procedure, describe salient points of factories act 1948 for health and safety, wash rooms, drinking water layouts, light, cleanliness, fire, guarding, pressure vessels, etc, Safety color codes. Fire prevention and firefighting, equipment and methods.

UNIT- II

Fundamentals of maintenance engineering: Definition and aim of maintenance engineering, Primary and secondary functions and responsibility of maintenance department, Types of maintenance, Types and applications of tools used for maintenance, Maintenance cost & its relation with replacement economy, Service life of equipment.

UNIT- III

Wear and Corrosion and their prevention: Wear- types, causes, effects, wear reduction methods, lubricants-types and applications, Lubrication methods, general sketch, working and applications,

- i. Screw down grease cup,
- ii. Pressure grease gun,
- iii. Splash lubrication,
- iv. Gravity lubrication,
- v. Wick feed lubrication
- vi. Side feed lubrication,
- vii. Ring lubrication,

Definition, principle and factors affecting the corrosion. Types of corrosion, corrosion prevention methods.

UNIT- IV

Fault tracing: Fault tracing-concept and importance, decision tree concept, need and applications, sequence of fault-finding activities, show as decision tree, draw decision tree for problems in machine tools, hydraulic, pneumatic, automotive, thermal and electrical equipment's like,

- i. Any one machine tool,
- ii. Pump
- iii. Air compressor
- iv. Internal combustion engine,
- v. Boiler,
- vi. Electrical motors, Types of faults in machine tools and their general causes.

UNIT- V

Periodic and preventive maintenance: Periodic inspection-concept and need, degreasing, cleaning and repairing schemes, overhauling of mechanical components, overhauling of electrical motor, common troubles and remedies of electric motor, repair complexities and its use, definition, need, steps and advantages of preventive maintenance. Steps/procedure for periodic and preventive maintenance of:

- i. Machine tools,
- ii. Pumps,
- iii. Air compressors,
- iv. Diesel generating (DG) sets,

Program and schedule of preventive maintenance of mechanical and electrical equipment, Advantages of preventive maintenance. Repair cycle concept and importance

REFERENCE BOOKS:

1. Maintenance Engineering Handbook, Higgins & Morrow, Da Information Services.
2. Maintenance Engineering, H. P. Garg, S. Chand and Company.
3. Pump-hydraulic Compressors, Audels, McGraw Hill Publication.
4. Foundation Engineering Handbook, Winterkorn, Hans, Chapman & Hall London.

Operations Research (Open Elective)

M.Tech. I Year II Sem.

L T P C

Course Code: M25VL306

3 0 0 3

Prerequisite: None

Course Outcomes: At the end of the course, the student should be able to

- Students should be able to apply the dynamic programming to solve problems of discrete and continuous variables.
- Students should be able to apply the concept of non-linear programming
- Students should be able to carry out sensitivity analysis
- Student should be able to model the real-world problem and simulate it.

UNIT- I

Optimization Techniques, Model Formulation, models, General L.R Formulation, Simplex Techniques, Sensitivity Analysis, Inventory Control Models

UNIT- II

Formulation of a LPP - Graphical solution revised simplex method - duality theory – dual simplex method

- sensitivity analysis - parametric programming

UNIT- III

Nonlinear programming problem - Kuhn-Tucker conditions min cost flow problem – max flow problem - CPM/PERT

UNIT- IV

Scheduling and sequencing - single server and multiple server models – deterministic inventory models

- Probabilistic inventory control models - Geometric Programming.

UNIT- V

Competitive Models, Single and Multi-channel Problems, Sequencing Models, Dynamic Programming, Flow in Networks, Elementary Graph Theory, Game Theory Simulation

TEXT BOOKS/ REFERENCE BOOKS:

1. H.A. Taha, Operations Research, An Introduction, PHI, 2008
2. H.M. Wagner, Principles of Operations Research, PHI, Delhi, 1982.
3. J.C. Pant, Introduction to Optimization: Operations Research, Jain Brothers, Delhi, 2008
4. Hitler Libermann Operations Research: McGraw Hill Pub. 2009
5. Pannerselvam, Operations Research: Prentice Hall of India 2010
6. Harvey M Wagner, Principles of Operations Research: Prentice Hall of India 2010

Cost Management of Engineering Projects (Open Elective)

M.Tech. I Year II Sem.

L T P C

Course Code:M25MB310

3 0 0 3

Prerequisite: None

UNIT- I

Introduction and Overview of the Strategic Cost Management Process Cost concepts in decision-making; Relevant cost, Differential cost, Incremental cost and Opportunity cost. Objectives of a Costing System; Inventory valuation; Creation of a Database for operational control; Provision of data for Decision-Making.

UNIT- II

Project: meaning, Different types, why to manage, cost overruns centres, various stages of project execution: conception to commissioning. Project execution as conglomeration of technical and nontechnical activities. Detailed Engineering activities. Pre-project execution main clearances and documents Project team: Role of each member. Importance Project site: Data required with significance. Project contracts. Types and contents. Project execution Project cost control. Bar charts and Network diagram. Project commissioning: mechanical and process

UNIT- III

Cost Behavior and Profit Planning Marginal Costing; Distinction between Marginal Costing and Absorption Costing; Break-even Analysis, Cost-Volume-Profit Analysis. Various decision-making problems. Standard Costing and Variance Analysis. Pricing strategies: Pareto Analysis. Target costing, Life Cycle Costing. Costing of service sector. Just-in-time approach, Material Requirement Planning, Enterprise Resource Planning, Total Quality Management and Theory of constraints.

UNIT- IV

Activity-Based Cost Management, Bench Marking; Balanced Score Card and Value-Chain Analysis. Budgetary Control; Flexible Budgets; Performance budgets; Zero-based budgets. Measurement of Divisional profitability pricing decisions including transfer pricing.

UNIT- V

Quantitative techniques for cost management, Linear Programming, PERT/CPM, Transportation problems, Assignment problems, Simulation, Learning Curve Theory.

TEXT BOOKS/ REFERENCE BOOKS:

1. Cost Accounting A Managerial Emphasis, Prentice Hall of India, New Delhi
2. Charles T. Horngren and George Foster, Advanced Management Accounting
3. Robert S Kaplan Anthony A. Alkinson, Management & Cost Accounting
4. Ashish K. Bhattacharya, Principles & Practices of Cost Accounting A. H. Wheeler publisher
5. N.D. Vohra, Quantitative Techniques in Management, Tata McGraw Hill Book Co. Ltd.

Composite Materials (Open Elective)

M.Tech. I Year II Sem.
Course Code:M25VL307

L T P C
3 0 0 3

Prerequisite: None

UNIT- I

INTRODUCTION: Definition – Classification and characteristics of Composite materials. Advantages and application of composites. Functional requirements of reinforcement and matrix. Effect of reinforcement (size, shape, distribution, volume fraction) on overall composite performance.

UNIT – II

REINFORCEMENTS: Preparation-layup, curing, properties and applications of glass fibers, carbon fibers, Kevlar fibers and Boron fibers. Properties and applications of whiskers, particle reinforcements. Mechanical Behavior of composites: Rule of mixtures, Inverse rule of mixtures. Isostrain and Isostress conditions.

UNIT – III

Manufacturing of Metal Matrix Composites: Casting – Solid State diffusion technique, Cladding – Hot isostatic pressing. Properties and applications. Manufacturing of Ceramic Matrix Composites: Liquid Metal Infiltration – Liquid phase sintering. Manufacturing of Carbon – Carbon composites: Knitting, Braiding, Weaving. Properties and applications.

UNIT- IV

Manufacturing of Polymer Matrix Composites: Preparation of Moulding compounds and prepregs – hand layup method – Autoclave method – Filament winding method – Compression moulding – Reaction injection moulding. Properties and applications.

UNIT – V

Strength: Laminar Failure Criteria-strength ratio, maximum stress criteria, maximum strain criteria, interacting failure criteria, hygrothermal failure. Laminate first ply failure-insight strength; Laminate strength-ply discount truncated maximum strain criterion; strength design using caplet plots; stress concentrations.

TEXT BOOKS/ REFERENCE BOOKS:

1. Material Science and Technology – Vol 13 – Composites by R.W.Cahn – VCH, West Germany.
2. Materials Science and Engineering, An introduction. WD Callister, Jr., Adapted by R. Balasubramaniam, John Wiley & Sons, NY, Indian edition, 2007.
3. Hand Book of Composite Materials-ed-Lubin.
4. Composite Materials – K. K. Chawla.
5. Composite Materials Science and Applications – Deborah D. L. Chung.
6. Composite Materials Design and Applications – Danial Gay, Suong V. Hoa, and Stephen W. Tasi.

English for Research Paper Writing (Audit Courses)

M.Tech. I Year II Sem.

Course Code: M25AC101

Prerequisite: None

Course objectives: Students will be able to:

- Understand that how to improve your writing skills and level of readability
- Learn about what to write in each section
- Understand the skills needed when writing a Title Ensure the good quality of paper at very first-time submission

UNIT-I:

Planning and Preparation, Word Order, Breaking up long sentences, Structuring Paragraphs and Sentences, Being Concise and Removing Redundancy, Avoiding Ambiguity and Vagueness

UNIT-II:

Clarifying Who Did What, Highlighting Your Findings, Hedging and Criticizing, Paraphrasing and Plagiarism, Sections of a Paper, Abstracts. Introduction

UNIT-III:

Review of the Literature, Methods, Results, Discussion, Conclusions, The Final Check.

UNIT-IV:

key skills are needed when writing a Title, key skills are needed when writing an Abstract, key skills are needed when writing an Introduction, skills needed when writing a Review of the Literature,

UNIT-V:

skills are needed when writing the Methods, skills needed when writing the Results, skills are needed when writing the Discussion, skills are needed when writing the Conclusions. useful phrases, how to ensure paper is as good as it could possibly be the first- time submission

TEXT BOOKS/ REFERENCES:

1. Goldbort R (2006) Writing for Science, Yale University Press (available on Google Books)
2. Day R (2006) How to Write and Publish a Scientific Paper, Cambridge University Press
3. Highman N (1998), Handbook of Writing for the Mathematical Sciences, SIAM. Highman's book.
4. Adrian Wallwork, English for Writing Research Papers, Springer New York Dordrecht Heidelberg London, 2011

Disaster Management (Audit Courses)

M.Tech. I Year II Sem.

Course Code: M25AC102

Prerequisite: None

Course Objectives: Students will be able to

1. learn to demonstrate a critical understanding of key concepts in disaster risk reduction and humanitarian response.
2. critically evaluate disaster risk reduction and humanitarian response policy and practice from multiple perspectives.
3. develop an understanding of standards of humanitarian response and practical relevance in specific types of disasters and conflict situations.
4. critically understand the strengths and weaknesses of disaster management approaches,
5. planning and programming in different countries, particularly their home country or the countries they work in

UNIT-I:

Introduction:

Disaster: Definition, Factors and Significance; Difference Between Hazard and Disaster; Natural and Manmade Disasters: Difference, Nature, Types and Magnitude.

Disaster Prone Areas in India:

Study of Seismic Zones; Areas Prone to Floods and Droughts, Landslides and Avalanches; Areas Prone to Cyclonic and Coastal Hazards with Special Reference to Tsunami; Post-Disaster Diseases and Epidemics

UNIT-II:

Repercussions of Disasters and Hazards:

Economic Damage, Loss of Human and Animal Life, Destruction of Ecosystem. Natural Disasters: Earthquakes, Volcanisms, Cyclones, Tsunamis, Floods, Droughts and Famines, Landslides and Avalanches, Man-made disaster: Nuclear Reactor Meltdown, Industrial Accidents, Oil Slicks and Spills, Outbreaks of Disease and Epidemics, War and Conflicts.

UNIT-III:

Disaster Preparedness and Management:

Preparedness: Monitoring of Phenomena Triggering A Disaster or Hazard; Evaluation of Risk: Application of Remote Sensing, Data from Meteorological and Other Agencies, Media Reports: Governmental and Community Preparedness.

UNIT-IV:

Risk Assessment Disaster Risk:

Concept and Elements, Disaster Risk Reduction, Global and National Disaster Risk Situation. Techniques of Risk Assessment, Global Co-Operation in Risk Assessment and Warning, People's Participation in Risk Assessment. Strategies for Survival.

UNIT-V:

Disaster Mitigation:

Meaning, Concept and Strategies of Disaster Mitigation, Emerging Trends In Mitigation. Structural Mitigation and Non-Structural Mitigation, Programs of Disaster Mitigation in India.

TEXT BOOKS/ REFERENCES:

1. R. Nishith, Singh AK, "Disaster Management in India: Perspectives, issues and strategies ""NewRoyal book Company.
2. Sahni, Pardeep Et. Al. (Eds.), "Disaster Mitigation Experiences and Reflections", Prentice Hall of India, New Delhi.
3. Goel S. L., Disaster Administration and Management Text and Case Studies", Deep & Deep Publication Pvt. Ltd., New Delhi.

Sanskrit For Technical Knowledge (Audit Courses)

M.Tech. I Year II Sem.

Course Code: M25AC103

Course Objectives:

1. To get a working knowledge in illustrious Sanskrit, the scientific language in the world
2. Learning of Sanskrit to improve brain functioning
3. Learning of Sanskrit to develop the logic in mathematics, science & other subjects enhancing the memory power
4. The engineering scholars equipped with Sanskrit will be able to explore the huge knowledge from ancient literature

UNIT-I:

Alphabets in Sanskrit,

UNIT-II:

Past/Present/Future Tense, Simple Sentences

UNIT-III:

Order, Introduction of roots,

UNIT-IV:

Technical information about Sanskrit Literature

UNIT-V:

Technical concepts of Engineering-Electrical, Mechanical, Architecture, Mathematics

TEXT BOOKS/ REFERENCES:

1. "Abhyaspustakam" – Dr. Vishwas, Samskrita-Bharti Publication, New Delhi
2. "Teach Yourself Sanskrit" Prathama Deeksha-Vempati Kutumbshastri, Rashtriya Sanskrit Sansthanam, New Delhi Publication
3. "India's Glorious Scientific Tradition" Suresh Soni, Ocean books (P) Ltd., New Delhi.

Course Outcomes: Students will be able to

4. Understanding basic Sanskrit language
5. Ancient Sanskrit literature about science & technology can be understood
6. Being a logical language will help to develop logic in students

Value Education (Audit Courses)

M.Tech. I Year II Sem.

Course Code: M25AC104

Prerequisite: None

Course Objectives: Students will be able to

1. Understand value of education and self- development
2. Imbibe good values in students
3. Let the should know about the importance of character

UNIT-I:

Values and self-development –Social values and individual attitudes. Work ethics, Indian vision of humanism. Moral and non- moral valuation. Standards and principles. Value judgements

UNIT-II:

Importance of cultivation of values. Sense of duty. Devotion, Self-reliance. Confidence, Concentration. Truthfulness, Cleanliness. Honesty, Humanity. Power of faith, National Unity. Patriotism. Love for nature, Discipline

UNIT-III:

Personality and Behavior Development - Soul and Scientific attitude. Positive Thinking. Integrity and discipline, Punctuality, Love and Kindness.

UNIT-IV:

Avoid fault Thinking. Free from anger, Dignity of labour. Universal brotherhood and religious tolerance. True friendship. Happiness Vs suffering, love for truth. Aware of self-destructive habits. Association and Cooperation. Doing best for saving nature

UNIT-V:

Character and Competence –Holy books vs Blind faith. Self-management and Good health. Science of reincarnation, Equality, Nonviolence, Humility, Role of Women. All religions and same message. Mind your Mind, Self-control. Honesty, Studying effectively

TEXT BOOKS/ REFERENCES:

1. Chakroborty, S.K. “Values and Ethics for organizations Theory and practice”, Oxford University Press, New Delhi

Course outcomes: Students will be able to

1. Knowledge of self-development
2. Learn the importance of Human values
3. Developing the overall personality

Constitution of India (Audit Courses)

M.Tech. I Year II Sem.

Course Code: M25AC105

Prerequisite: None

Course Objectives: Students will be able to:

- Understand the premises informing the twin themes of liberty and freedom from a civil rights perspective.
- To address the growth of Indian opinion regarding modern Indian intellectuals' constitutional role and entitlement to civil and economic rights as well as the emergence of nationhood in the early years of Indian nationalism.
- To address the role of socialism in India after the commencement of the Bolshevik Revolution in 1917 and its impact on the initial drafting of the Indian Constitution.

UNIT-I:

History of Making of the Indian Constitution: History Drafting Committee, (Composition & Working),

Philosophy of the Indian Constitution: Preamble, Salient Features.

UNIT-II:

Contours of Constitutional Rights & Duties: Fundamental Rights Right to Equality, Right to Freedom, Right against Exploitation, Right to Freedom of Religion, Cultural and Educational Rights, Right to Constitutional Remedies, Directive Principles of State Policy, Fundamental Duties.

UNIT-III:

Organs of Governance: Parliament, Composition, Qualifications and Disqualifications, Powers and Functions, Executive, President, Governor, Council of Ministers, Judiciary, Appointment and Transfer of Judges, Qualification, Powers and Functions.

UNIT-IV:

Local Administration: District's Administration head: Role and Importance, Municipalities: Introduction, Mayor and role of Elected Representative, CEO of Municipal Corporation. Pachayati raj: Introduction, PRI: Zila Pachayat. Elected officials and their roles, CEO Zila Pachayat: Position and role. Block level: Organizational Hierarchy (Different departments), Village level: Role of Elected and Appointed officials, Importance of grass root democracy.

UNIT-V:

Election Commission: Election Commission: Role and Functioning. Chief Election Commissioner and Election Commissioners. State Election Commission: Role and Functioning. Institute and Bodies for the welfare of SC/ST/OBC and women.

TEXT BOOKS/ REFERENCES:

1. The Constitution of India, 1950 (Bare Act), Government Publication.
2. Dr. S. N. Busi, Dr. B. R. Ambedkar framing of Indian Constitution, 1st Edition, 2015.
3. M. P. Jain, Indian Constitution Law, 7th Edn., Lexis Nexis, 2014.
4. D.D. Basu, Introduction to the Constitution of India, Lexis Nexis, 2015.

Course Outcomes: Students will be able to:

1. Discuss the growth of the demand for civil rights in India for the bulk of Indians before the arrival of Gandhi in Indian politics.
2. Discuss the intellectual origins of the framework of argument that informed the conceptualization of social reforms leading to revolution in India.
3. Discuss the circumstances surrounding the foundation of the Congress Socialist Party [CSP] under the leadership of Jawaharlal Nehru and the eventual failure of the proposal of direct elections through adult suffrage in the Indian Constitution.
4. Discuss the passage of the Hindu Code Bill of 1956.

Pedagogy Studies (Audit Courses)

M.Tech. I Year II Sem.

Course Code: M25AC106

Prerequisite: None

Course Objectives: Students will be able to:

1. Review existing evidence on the review topic to inform programme design and policy making undertaken by the DfID, other agencies and researchers.
2. Identify critical evidence gaps to guide the development.

UNIT-I:

Introduction and Methodology: Aims and rationale, Policy background, Conceptual framework and terminology Theories of learning, Curriculum, Teacher education. Conceptual framework, Research questions. Overview of methodology and Searching.

UNIT-II:

Thematic overview: Pedagogical practices are being used by teachers in formal and informal classrooms in developing countries. Curriculum, Teacher education.

UNIT-III:

Evidence on the effectiveness of pedagogical practices, Methodology for the indepth stage: quality assessment of included studies. How can teacher education (curriculum and practicum) and the scho curriculum and guidance materials best support effective pedagogy? Theory of change. Strength and nature of the body of evidence for effective pedagogical practices. Pedagogic theory and pedagogical approaches. Teachers' attitudes and beliefs and Pedagogic strategies.

UNIT-IV:

Professional development: alignment with classroom practices and follow-up support, Peer support, Support from the head teacher and the community. Curriculum and assessment, Barriers to learning: limited resources and large class sizes

UNIT-V:

Research gaps and future directions: Research design, Contexts, Pedagogy, Teacher education, Curriculum and assessment, Dissemination and research impact.

TEXT BOOKS/ REFERENCES:

1. Ackers J, Hardman F (2001) Classroom interaction in Kenyan primary schools, *Compare*, 31(2): 245-261.
2. Agrawal M (2004) Curricular reform in schools: The importance of evaluation, *Journal of Curriculum Studies*, 36 (3): 361-379.
3. Akyeampong K (2003) Teacher training in Ghana - does it count? Multi-site teacher education research project (MUSTER) country report 1. London: DFID.
4. Akyeampong K, Lussier K, Pryor J, Westbrook J (2013) Improving teaching and learning of basic maths and reading in Africa: Does teacher preparation count? *International Journal Educational Development*, 33 (3): 272–282.
5. Alexander RJ (2001) *Culture and pedagogy: International comparisons in primary education*. Oxford and Boston: Blackwell.
6. Chavan M (2003) Read India: A mass scale, rapid, 'learning to read' campaign.
7. www.pratham.org/images/resource%20working%20paper%202.pdf.

Course Outcomes: Students will be able to understand:

1. What pedagogical practices are being used by teachers in formal and informal classrooms in developing countries?
2. What is the evidence on the effectiveness of these pedagogical practices, in what conditions, and with what population of learners?
3. How can teacher education (curriculum and practicum) and the school curriculum and guidance materials best support effective pedagogy?

Stress Management by Yoga (Audit Courses)

M.Tech. I Year II Sem.

Course Code: M25AC107

Prerequisite: None

Course Objectives:

- To achieve overall health of body and mind
- To overcome stress

Course Outcomes: Students will be able to:

- Develop healthy mind in a healthy body thus improving social health also
- Improve efficiency

UNIT-I:

Definitions of Eight parts of yog. (Ashtanga)

UNIT-II:

Yam and Niyam.

UNIT-III:

Do's and Don't's in life.

- i) Ahinsa, satya, astheya, bramhacharya and aparigraha
- ii) Shaucha, santosh, tapa, swadhyay, ishwarpranidhan

UNIT-IV:

Asan and Pranayam

UNIT-V:

- i) Various yog poses and their benefits for mind & body
- ii) Regularization of breathing techniques and its effects-Types of pranayam

TEXT BOOKS/ REFERENCES:

1. 'Yogic Asanas for Group Training-Part-I': Janardan Swami Yogabhyasi Mandal, Nagpur
2. "Rajayoga or conquering the Internal Nature" by Swami Vivekananda, Advaita Ashrama (Publication Department), Kolkata

Personality Development Through Life Enlightenment Skills

(Audit Courses)

M.Tech. I Year II Sem.

Course Code: M25AC108

Prerequisite: None

Course Objectives:

1. To learn to achieve the highest goal happily
2. To become a person with stable mind, pleasing personality and determination
3. To awaken wisdom in students

UNIT-I:

Neetisatakam-Holistic development of personality

- Verses- 19,20,21,22 (wisdom)
- Verses- 29,31,32 (pride & heroism)
- Verses- 26,28,63,65 (virtue)

UNIT-II:

Neetisatakam-Holistic development of personality

- Verses- 52,53,59 (don't's)
- Verses- 71,73,75,78 (do's)

UNIT-III:

Approach to day to day work and duties.

- Shrimad Bhagwad Geeta: Chapter 2-Verses 41, 47,48,
- Chapter 3-Verses 13, 21, 27, 35, Chapter 6-Verses 5,13,17, 23, 35,
- Chapter 18-Verses 45, 46, 48.

UNIT-IV:

Statements of basic knowledge.

- Shrimad Bhagwad Geeta: Chapter2-Verses 56, 62, 68
- Chapter 12 -Verses 13, 14, 15, 16,17, 18
- Personality of Role model. Shrimad Bhagwad Geeta:

UNIT-V:

- Chapter2-Verses 17, Chapter 3-Verses 36,37,42,
- Chapter 4-Verses 18, 38,39
- Chapter18 – Verses 37,38,63

TEXT BOOKS/ REFERENCES:

1. "Srimad Bhagavad Gita" by Swami Swarupananda Advaita Ashram (Publication Department),Kolkata.
2. Bhartrihari's Three Satakam (Niti-sringar-vairagya) by P.Gopinath, Rashtriya SanskritSansthanam, New Delhi.

Course Outcomes: Students will be able to

1. Study of Shrimad-Bhagwad-Geeta will help the student in developing his personality and achieve the highest goal in life
2. The person who has studied Geeta will lead the nation and mankind to peace and prosperity
3. Study of Neetishatakam will help in developing versatile personality of students